

TRF1305C2 5dB-Gain, Dual-Channel, DC to > 6.5GHz BW, RF Fully Differential Amp

1 Features

- Three performance-optimized power gain variants:
 - 15dB (TRF1305A2)
 - 10dB (TRF1305B2)
 - 5dB (TRF1305C2)
- Fixed gain can be reduced with external resistors
- Wide large-signal RF bandwidth:
 - D2D: 6.6GHz (3dB), 5.5GHz (1dB)
 - S2D: 6.6GHz (3dB), 4.9GHz (1dB)
- OP1dB (differential 100Ω load):
 - D2D: 14.6dBm (2GHz), 11.4dBm (4GHz)
 - S2D: 14.5dBm (2GHz), 11.4dBm (4GHz)
- OIP3 ($P_O = 1dBm/tone$):
 - D2D: 31.5dBm (2GHz), 23dBm (4GHz)
 - S2D: 30.5dBm (2GHz), 21dBm (4GHz)
- Noise Figure:
 - D2D: 13.3dB (2GHz), 15.3dB (4GHz)
 - S2D: 13.8dB (2GHz), 16.9dB (4GHz)
- Slew rate: 25kV/µs
- Large input (±1V) and output (±0.5V) commonmode voltage ranges
- Flexible configurations and modes:
 - Single-ended input, differential output (S2D)
 - Differential input, differential output (D2D)
 - AC- or DC-coupled input/output
 - Adjustable output common-mode voltage
 - Input common-mode range extension mode
- Supports 5V, single or split supplies
- Active power dissipation: 447.5mW per channel
- Power-down for each channel

2 Applications

- RF sampling or GSPS ADC driver
- Test and measurement
- Wireless communications test
- RF digitizers
- Oscilloscopes (DSOs)
- High speed digitizer
- Spectrum analyzer

- Vector signal transceiver (VST)
- Mass spectrometry systems
- Common-mode level shifting
- IQ mixer interface

3 Description

The TRF1305C2 is a very high performance, closed-loop, dual-channel RF amplifier that has an operational bandwidth from true-dc to >6.5GHz. The device has excellent performance to drive high-speed, high-performance ADCs, such as the ADC12DJ5200RF and ADC32RF5x with a dc- or accoupled interface. The amplifier is optimized for use in RF, zero and complex IF, and high-speed time-domain applications. The device is optimized for performance in the fixed gain configuration. If lower gain is desired, use external resistors.

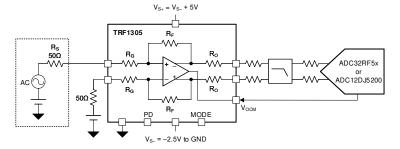
The TRF1305C2 features a VOCM pin that allows setting different output common-mode and input common-mode voltages; for example, level-shifting or for most IQ down-converter ADC-interface applications that have differing dc common-mode voltages. The TRF1305C2 also features a floating two-rail split or single-supply option, and a MODE pin that allows extending the input common-mode range closer to the supplies. The device also has a powerdown feature to turn-off each channel individually.

The device uses TI's proprietary advanced BiCMOS process and is available in a space-saving, 2.5mm × 3mm, 16-pin, WQFN-FCRLF package.

Device Information

| PART NUMBER ⁽¹⁾ | POWER GAIN | PACKAGE ⁽²⁾ |
|----------------------------|------------|-----------------------------------------|
| TRF1305A2 | 15dB | 5) (5) |
| TRF1305B2 | 10dB | RYP (WQFN-FCRLF, 16) |
| TRF1305C2 | 5dB | (************************************** |

- See Section 4.
- For more information, see Section 11.



TRF1305C2 in S2D Configuration Driving a High-Speed ADC



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4 Device Comparison Table

| DEVICE | GAIN | CHANNEL COUNT |
|-----------|------|---------------|
| TRF1305A1 | 15dB | |
| TRF1305B1 | 10dB | 1 |
| TRF1305C1 | 5dB | |
| TRF1305A2 | 15dB | |
| TRF1305B2 | 10dB | 2 |
| TRF1305C2 | 5dB | |

5 Pin Configuration and Functions

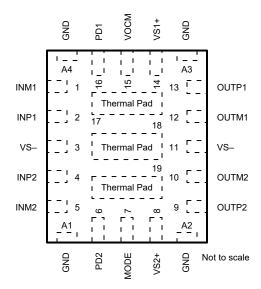


Figure 5-1. RYP Package (Dual-Channel), 16-Pin WQFN-FCRLF (Top View)

Table 5-1. Pin Functions

| | PIN | | |
|----------------|----------------|--------|-----------------------------------------------------------------------------------------------------------------------------------------------------|
| NAME | NO. | TYPE | DESCRIPTION |
| GND | A1, A2, A3, A4 | _ | Ground. Connect to ground plane on the board. Internally shorted to the thermal pad. |
| INM1 | 1 | Input | Negative side of differential input signal for channel 1 (Ch1). |
| INM2 | 5 | Input | Negative side of differential input signal for channel 2 (Ch2). |
| INP1 | 2 | Input | Positive side of differential input signal for channel 1 (Ch1). |
| INP2 | 4 | Input | Positive side of differential input signal for channel 2 (Ch2). |
| MODE | 7 | Input | Mode selection pin. For details, see the Mode Pin section. |
| OUTM1 | 12 | Output | Negative side of differential output signals for Ch1. |
| OUTM2 | 10 | Output | Negative side of differential output signals for Ch2. |
| OUTP1 | 13 | Output | Positive side of differential output signals for Ch1. |
| OUTP2 | 9 | Output | Positive side of differential output signals for Ch2. |
| PD1 | 16 | Input | Power-down signal for Ch1, referenced to GND. Supports both 1.8V and 3.3V logic. Logic 0 or open = channel enabled. Logic 1 = channel powered down. |
| PD2 | 6 | Input | Power-down signal for Ch2, referenced to GND. Supports both 1.8V and 3.3V Logic. Logic 0 or open = channel enabled. Logic 1 = channel powered down. |
| VOCM | 15 | Input | Output common-mode voltage input pin. Common for both channels. Float the pin to set the output common-mode voltage to V_{S-} + 2.5 V_{S-} |
| VS- | 3, 11 | Power | Negative supply pin. Common for both channels. |
| VS1+ | 14 | Power | Positive supply pin for Ch1. Ensure that $V_{S1+} = V_{S2+}$. |
| VS2+ | 8 | Power | Positive supply pin for Ch2. Ensure that V _{S1+} = V _{S2+} . |
| Thermal Pad | 17, 18, 19 | _ | Thermal pad. Connect to heat-dissipating ground plane on the board. Internally shorted to GND. |



6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

| | | | MIN | MAX | UNIT |
|-------------------|--------------------------------------------------------------------------|--------------------------------------------|----------------------|-----------------------|------|
| V _{S-} | Negative supply voltage, referenced to G | Negative supply voltage, referenced to GND | | 0.3 | V |
| V _{S+} | Positive supply voltage, ensure that V _{S1+} | = V _{S2+} | -0.3 | V _{S-} + 5.5 | V |
| Vs | Total supply voltage, V _S = V _{S+} – V _{S-} | | -0.3 | 5.5 | V |
| P _{IN} | Input RF power ⁽²⁾ | | | 20 | dBm |
| \/ | PD pin voltage, referenced to GND | V _{S+} ≥ 3.3V | -0.3 | 3.6 | V |
| V _{PD} | | V _{S+} < 3.3V | -0.3 | V _{S+} + 0.3 | |
| V _{OCM} | VOCM pin voltage | | V _{S-} + 1 | V _{S-} + 4 | V |
| V _{MODE} | MODE pin voltage | | V _{S-} -0.3 | V _{S-} + 3.3 | V |
| TJ | Junction temperature | | -40 | 150 | °C |
| T _{stg} | Storage temperature | | -40 | 150 | °C |

⁽¹⁾ Operation outside the Absolute Maximum Ratings may cause permanent device damage. Absolute Maximum Ratings do not imply functional operation of the device at these or any other conditions beyond those listed under Recommended Operating Conditions. If used outside the Recommended Operating Conditions but within the Absolute Maximum Ratings, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.

6.2 ESD Ratings

| | | | VALUE | UNIT |
|--------------------------------------------|---------------------------------------------------------------------------------|-----------------------------------------------------------------------------|-------|------|
| V | V Flacture static dischause | Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins ⁽¹⁾ | ±1000 | \/ |
| V _(ESD) Electrostatic discharge | Charged device model (CDM), per ANSI/ESDA/JEDEC JS-002, all pins ⁽²⁾ | ±500 | V | |

⁽¹⁾ JEDEC document JEP155 states that 500V HBM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

| | | MIN | NOM | MAX | UNIT |
|-----------------|-----------------------------------------------|------|-----|------|------|
| V _{S-} | Negative supply voltage | -2.5 | | 0 | V |
| Vs | Total supply voltage, $V_S = V_{S+} - V_{S-}$ | 4.75 | 5 | 5.25 | V |
| TJ | Junction temperature | -40 | | 125 | °C |

6.4 Thermal Information

| | | TRF1305C2 | |
|-----------------------|----------------------------------------------|------------------|------|
| | THERMAL METRIC ⁽¹⁾ | RYP (WQFN-FCRLF) | UNIT |
| | | 16 PINS | |
| $R_{\theta JA}$ | Junction-to-ambient thermal resistance | 51.8 | °C/W |
| R _{0JC(top)} | Junction-to-case (top) thermal resistance | 24.5 | °C/W |
| R _{θJB} | Junction-to-board thermal resistance | 14.5 | °C/W |
| Ψ_{JT} | Junction-to-top characterization parameter | 1.4 | °C/W |
| Ψ_{JB} | Junction-to-board characterization parameter | 14.3 | °C/W |
| R _{0JC(bot)} | Junction-to-case (bottom) thermal resistance | 10.7 | °C/W |

(1) For information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

⁽²⁾ When device supplies are present; otherwise, limit swing at the device pins to $V_{S-} \pm 0.3V$.

⁽²⁾ JEDEC document JEP157 states that 250V CDM allows safe manufacturing with a standard ESD control process.



6.5 Electrical Characteristics - AC Specifications in D2D Configuration

at T_A = 25°C, V_{S+} = 5V, V_{S-} = 0V, floating VOCM, PD, and MODE pins, V_{ICM} = midsupply, D2D ac-coupled input/output with differential source impedance (Z_S) = 100 Ω , differential output load (Z_L) = 100 Ω , external input resistor network (see Figure 8-3), and inputs de-embedded up to R_{IN} SH and outputs up to the device pins (unless otherwise noted)

| | PARAMETER | TEST COND | ITIONS | MIN | TYP | MAX | UNIT |
|---------|-------------------------------------|-----------------------------------------------------------|------------|-----|-------------|-----|-------|
| AC PERI | FORMANCE | | | | | | |
| 00011 | Small-signal bandwidth (3dB) | P _{IN} = –20dBm at each in | put | | 6.8 | | |
| SSBW | Small-signal bandwidth (1dB) | P _{IN} = –20dBm at each in | put | | 5.5 | | GHz |
| | Large-signal bandwidth (3dB) | Differential P _{IN} = 2dBm | | | 6.6 | | |
| LSBW | Large-signal bandwidth (1dB) | Differential P _{IN} = 2dBm | | | 5.5 | | GHz |
| | | f = 500MHz | | | 5.5 | | |
| Sdd21 | Power gain | f = 4GHz | | | 5.9 | | dB |
| | Gain variation over temperature | f = 4GHz, T _A = -40°C to | +85°C | | 0.9 | | dB |
| Sdd11 | Input return loss | f = 10MHz to 5GHz | | | -14 | | dB |
| Sdd12 | Reverse isolation | f < 5GHz (device enabled | d) | | -21 | | dB |
| | Gain mismatch between channels | f = 10MHz to 5GHz | | | ±0.25 | | dB |
| | Phase mismatch between channels | f = 10MHz to 5GHz | | | ±2 | | 0 |
| | Crosstalk between channels | f = 1GHz | | | -64 | | dBc |
| | | f = 500MHz | | | 14.7 | | |
| | | f = 1GHz | | | 15 | | |
| 00410 | | f = 2GHz | | | 14.6 | | |
| OP1dB | Output 1dB compression point | f = 3GHz | | | 13.6 | | dBm |
| | | f = 4GHz | | | 11.4 | | |
| | | f = 5GHz | | | 9.9 | | |
| | Second-order harmonic distortion | V _O = 2V _{PP} (P _O = 7dBm) | f = 500MHz | | -81 | | |
| | | | f = 1GHz | | -68 | | dBc |
| HD2 | | | f = 2GHz | | -62 | | |
| | | | f = 3GHz | | -55 | | |
| | | | f = 4GHz | | -47 | | |
| | | | f = 500MHz | | -66 | | |
| | | | f = 1GHz | | -58 | | |
| HD3 | Third-order harmonic distortion | $V_O = 2V_{PP} (P_O = 7dBm)$ | f = 2GHz | | -54 | | dBc |
| | | | f = 3GHz | | – 51 | | |
| | | | f = 4GHz | | -46 | | |
| | | | f = 500MHz | | 85 | | |
| | | | f = 1GHz | | 71 | | |
| OIP2 | Output second-order intercept point | P _O = 1dBm per tone, | f = 2GHz | | 63 | | dBm |
| OIFZ | Output second-order intercept point | 2MHz spacing | f = 3GHz | | 57 | | ubili |
| | | | f = 4GHz | | 52 | | |
| | | | f = 5GHz | | 47 | | |
| | | | f = 500MHz | | 41 | | |
| | | | f = 1GHz | | 37 | | dBm |
| OIP3 | Output third-order intercept point | P _O = 1dBm per tone, | f = 2GHz | | 31.5 | | |
| OII 0 | Salpat tilla-order intercept politi | 2MHz spacing | f = 3GHz | | 28.5 | | |
| | | | f = 4GHz | | 23 | | |
| | | | f = 5GHz | | 17 | | |



6.5 Electrical Characteristics - AC Specifications in D2D Configuration (continued)

at T_A = 25°C, V_{S+} = 5V, V_{S-} = 0V, floating VOCM, PD, and MODE pins, V_{ICM} = midsupply, D2D ac-coupled input/output with differential source impedance (Z_S) = 100 Ω , differential output load (Z_L) = 100 Ω , external input resistor network (see Figure 8-3), and inputs de-embedded up to R_{IN} SH and outputs up to the device pins (unless otherwise noted)

| | PARAMETER | TEST CONDITIONS | MIN TYP | MAX | UNIT |
|-----|-------------------------------|-----------------|---------|-----|----------|
| | | f = 500MHz | 10 | | |
| | | f = 1GHz | 11.5 | | |
| NF | Noise figure | f = 2GHz | 13.3 | | dB |
| | Noise figure | f = 3GHz | 14.4 | | uБ |
| | | f = 4GHz | 15.3 | | |
| | | f = 5GHz | 16 | | |
| | | f = 500MHz | -157.9 | | |
| | | f = 1GHz | -156.9 | | |
| NCD | Output paige appatral density | f = 2GHz | -154.8 | | dBm/Hz |
| NSD | Output noise spectral density | f = 3GHz | -153.6 | | UDIII/HZ |
| | | f = 4GHz | -152.6 | | |
| | | f = 5GHz | -152.8 | | |



6.6 Electrical Characteristics - AC Specifications in S2D Configuration

| | PARAMETER | TEST COND | ITIONS | MIN | TYP | MAX | UNIT |
|-------------------|-------------------------------------|-------------------------------------|-------------------------|-----|-------------|-----|------------|
| AC PERI | FORMANCE | | | 1 | | | |
| 00014 | Small-signal bandwidth (3dB) | P _{IN} = –20dBm at each in | put | | 6.8 | | |
| SSBW | Small-signal bandwidth (1dB) | P _{IN} = –20dBm at each in | put | | 5.2 | | GHz |
| | Large-signal bandwidth (3dB) | Single-ended P _{IN} = 2dBn | า | | 6.6 | | |
| LSBW | Large-signal bandwidth (1dB) | Single-ended P _{IN} = 2dBn | | | 4.9 | | GHz |
| 0.1.04 | | f = 500MHz | | | 5.2 | | |
| Sds21 | Power gain | f = 4GHz | | | 5 | | dB |
| | Gain variation over temperature | $f = 4GHz$, $T_A = -40$ °C to | +85°C | | 1.5 | | dB |
| Sss11 | Input return loss | f = 10MHz to 5GHz | | | -12 | | dB |
| Ssd12 | Reverse isolation | f < 5GHz (device enabled | d) | | -22 | | dB |
| | Gain mismatch between channels | f = 10MHz to 5GHz | | | ±0.25 | | dB |
| | Phase mismatch between channels | f = 10MHz to 5GHz | | | ±2 | | 0 |
| | Crosstalk between channels | f = 1GHz | | | -46 | | dBc |
| G _{IMB} | Differential output gain imbalance | f < 5GHz, P _{IN} = -20dBm | with 50Ω Z _S | | ±0.8 | | dB |
| PH _{IMB} | Differential output phase imbalance | f < 5GHz, P _{IN} = -20dBm | with 50Ω Z _S | | ±1.5 | | 0 |
| | Output 1dB compression point | f = 500MHz | | | 14.8 | | - |
| | | f = 1GHz | | | 15 | | |
| ODAJD | | f = 2GHz | f = 2GHz | | 14.5 | | .ID |
| OP1dB | | f = 3GHz | | | 13.1 | | dBm |
| | | f = 4GHz | | | 11.4 | | |
| | | f = 5GHz | | | 10 | | |
| | | | f = 500MHz | | -63 | | |
| | | | f = 1GHz | | -50 | | |
| HD2 | Second-order harmonic distortion | $V_O = 2V_{PP} (P_O = 7dBm)$ | f = 2GHz | | -41 | | dBc |
| | | | f = 3GHz | | -30 | | |
| | | | f = 4GHz | | -29 | | |
| | | | f = 500MHz | | -67 | | |
| | | | f = 1GHz | | - 55 | | |
| HD3 | Third-order harmonic distortion | $V_O = 2V_{PP} (P_O = 7dBm)$ | f = 2GHz | | -44 | | dBc |
| | | | f = 3GHz | | -44 | | |
| | | | f = 4GHz | | -50 | | |
| | | | f = 500MHz | | 71 | | |
| | | | f = 1GHz | | 55 | | |
| OIP2 | Output second-order intercept point | P _O = 1dBm per tone, | f = 2GHz | | 43 | | - dBm - |
| OIFZ | Output second-order intercept point | 2MHz spacing | f = 3GHz | | 34 | | |
| | | | f = 4GHz | | 31 | | |
| | | | f = 5GHz | | 34 | | |



6.6 Electrical Characteristics - AC Specifications in S2D Configuration (continued)

at T_A = 25°C, V_{S+} = 5V, V_{S-} = 0V, floating VOCM, PD, and MODE pins, V_{ICM} = mid-supply, S2D ac-coupled input/output configuration with R_{TERM} = 50 Ω , Z_S = 50 Ω , Z_L = 100 Ω (see Figure 8-1), and input and outputs de-embedded up to the device pins (unless otherwise noted)

| | PARAMETER | TEST CON | TEST CONDITIONS | | TYP | MAX | UNIT |
|------|-------------------------------------------------------------------------------------------------------------------------------------|---------------------------------|-----------------|--|------------------------------------------------------------------------------------------------------------------------|-----|--------|
| | | | f = 500MHz | | 39.5 | | |
| | | | f = 1GHz | | 39.5 35.5 30.5 25.5 21 17.5 12.2 12.5 13.8 15.7 16.9 17.4 -156.7 -156.2 -155 | | |
| OIP3 | Output third-order intercept point | P _O = 1dBm per tone, | f = 2GHz | | 30.5 | | dBm |
| OIF3 | Output triird-order intercept point | 2MHz spacing | f = 3GHz | | 25.5 | | UDIII |
| | | | f = 4GHz | | 21 | | |
| | | | f = 5GHz | | 17.5 | | |
| | | f = 500MHz | | | 12.2 | | |
| NF | | f = 1GHz | | | 12.5 | | |
| | Noise figure | f = 2GHz | f = 2GHz | | 13.8 | | dB |
| INF | Noise ligure | f = 3GHz | | | 15.7 | | αв |
| | | f = 4GHz | | | 16.9 | | |
| | | f = 5GHz | | | 17.4 | | |
| | | f = 500MHz | | | -156.7 | | |
| | | f = 1GHz | | | -156.2 | | |
| NCD | f = 5GHz f = 500MHz f = 1GHz f = 2GHz f = 3GHz f = 4GHz f = 5GHz f = 4GHz f = 5GHz f = 5GHz Output noise spectral density | | -155 | | | | |
| เพอบ | Output noise spectral density | f = 3GHz | | | -153.3 | | dBm/Hz |
| | | f = 4GHz | f = 4GHz | | -152.2 | | |
| | | f = 5GHz | | | -151.7 | | |

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6.7 Electrical Characteristics - DC and Timing Specifications

at T_A = 25°C, V_{S+} = 5V, V_{S-} = 0V, floating VOCM, PD, and MODE pins, V_{ICM} = midsupply, Z_L = 100 Ω , and specifications apply to both S2D and D2D configuration (unless otherwise noted)

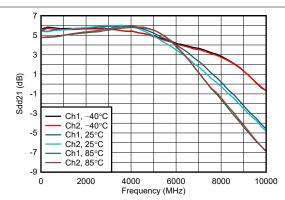
| | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT | |
|----------------------|-----------------------------------------------------------------|--------------------------------------------------------------------------------------------------------------------------------|-----------------------|------|---------------------|-----------------|--|
| DC PERF | FORMANCE | | 1 | | | | |
| V _{OD-MAX} | Max differential output voltage | f = 1GHz | | 4 | | V _{PP} | |
| | Slew rate | $2V V_O$ step, dc coupled, $V_{S+} = 2.5V$, $V_{S-} = -2.5V$ | | 25 | | kV/μs | |
| | Output differential offset voltage | | | ±3 | | mV | |
| | Overdrive recovery time | DC coupled, V_{S+} = 2.5V, V_{S-} = -2.5V, from 2 × overdrive of each SE output to each output voltage settling to < ±50mV | | 6 | | ns | |
| СОММО | N-MODE | | | | | | |
| V _{ICM} | Input common-mode voltage | Default range ⁽¹⁾ | V _{S-} + 1.5 | V: | _{S-} + 3.5 | V | |
| V _{OCM} | Output common-mode voltage | | V _{S-} + 2 | | V _{S-} + 3 | V | |
| | Output common-mode offset voltage from V _{OCM} voltage | | -20 | | 20 | mV | |
| IMPEDA | NCE | | | | | | |
| Z _{IN-SE} | Single-ended input impedance | S2D, at INP pin with 50Ω termination on INM pin | | 45 | | Ω | |
| Z _{IN-DIFF} | Differential input impedance | D2D, at the device pins | 33.3 | | Ω | | |
| | | D2D, at R _{IN_SH} , see Figure 8-3 | | 76.9 | | 12 | |
| Z _{O-DIFF} | Differential output impedance | f = near-dc | | 8 | | Ω | |
| POWER | SUPPLY | | | | , | | |
| I _{QA} | Active quiescent current | Both channels active | | 179 | | mA | |
| | | One channel active, other is powered down | | 100 | | A | |
| I _{QPD} | Power-down quiescent current | Both channels powered down | | 21 | | mA | |
| POWER | DOWN | | | | | | |
| V _{PD_Hi} | PD pin logic high | Referenced to GND, see Section 6.1 | 1.35 | | | V | |
| V _{PD_Lo} | PD pin logic low | Referenced to GND, see Section 6.1 | | | 0.3 | V | |
| I _{PD_Bias} | PD bias current (current on PD pin) | PD = high (1.8V logic) | | 10.5 | 15 | μA | |
| | | PD = high (3.3V logic) | | 19 | 30 | | |
| t _{ON} | Turn-on time | S2D, dc coupled, V_{S+} = 2.5V, V_{S-} = -2.5V, from 50% V_{PD} transition to 90% RF out | | 25 | | ns | |
| t _{OFF} | Turn-off time | S2D, dc coupled, V_{S+} = 2.5V, V_{S-} = -2.5V, from 50% V_{PD} transition to 10% RF out | | 20 | | ns | |

⁽¹⁾ V_{ICM} range can be extended closer to V_{S+} or V_{S-} in D2D configuration. See also Section 7.4.1.

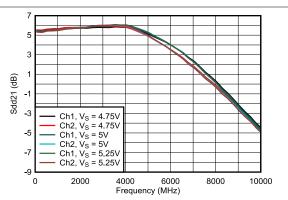


6.8 Typical Characteristics: D2D Configuration

at T_A = 25°C, V_{S+} = 5V, V_{S-} = 0V, floating VOCM, PD, and MODE pins, V_{ICM} = mid-supply, D2D ac-coupled input/output configuration with Z_S = 100 Ω , Z_L = 100 Ω , external input resistor network (see Figure 8-3), inputs de-embedded up to R_{IN_SH} and outputs up to the device pins, ambient temperatures shown, and resistor network included as part of DUT characteristic plots (unless otherwise noted)

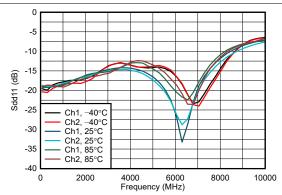


 P_{IN} = -20dBm with 50Ω source at all excited ports, nonexcited ports are terminated with 50Ω



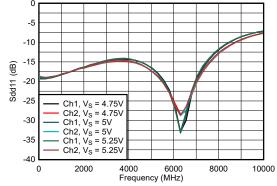
 P_{IN} = -20dBm with 50 Ω source at all excited ports, nonexcited ports are terminated with 50 Ω





 $P_{IN} = -20 dBm \ with \ 50 \Omega \ source \ at \ all \ excited \ ports,$ nonexcited ports are terminated with \ 50 \Omega \

Figure 6-2. Power Gain (Sdd21) Across Supply Voltage



 $P_{\text{IN}} = -20 \text{dBm with } 50\Omega \text{ source at all excited ports,} \\ \text{nonexcited ports are terminated with } 50\Omega$

Figure 6-3. Input Return Loss (Sdd11) Across Temperature

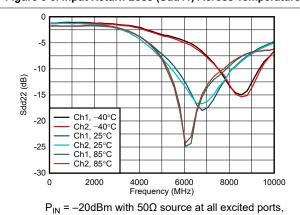
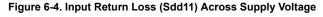
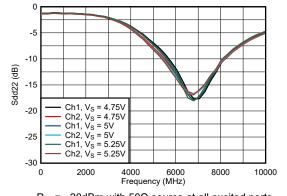


Figure 6-5. Output Return Loss (Sdd22) Across Temperature

nonexcited ports are terminated with 50Ω



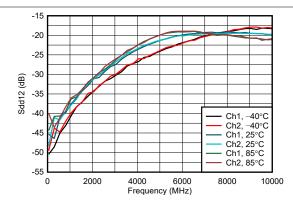


 P_{IN} = -20dBm with 50Ω source at all excited ports, nonexcited ports are terminated with 50Ω

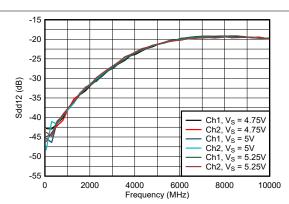
Figure 6-6. Output Return Loss (Sdd22) Across Supply Voltage



at T_A = 25°C, V_{S+} = 5V, V_{S-} = 0V, floating VOCM, PD, and MODE pins, V_{ICM} = mid-supply, D2D ac-coupled input/output configuration with Z_S = 100 Ω , Z_L = 100 Ω , external input resistor network (see Figure 8-3), inputs de-embedded up to R_{IN_SH} and outputs up to the device pins, ambient temperatures shown, and resistor network included as part of DUT characteristic plots (unless otherwise noted)



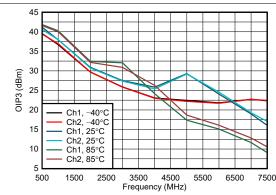
 P_{IN} = -20dBm with 50Ω source at all excited ports, nonexcited ports are terminated with 50Ω



 P_{IN} = -20dBm with 50Ω source at all excited ports, nonexcited ports are terminated with 50Ω

Figure 6-8. Reverse Isolation (Sdd12) Across Supply Voltage

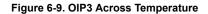
Figure 6-7. Reverse Isolation (Sdd12) Across Temperature



 $P_O = -5 dBm/tone$, 2MHz tone spacing

45 40 35 80 20 Ch1, V_S = 4.75V Ch2, V_S = 4.75V Ch1, V_S = 5.5V Ch2, V_S = 5.5V Ch2, V_S = 5.25V Ch2, V_S = 5.25V

1500 2500 3500 4500 5500 6500 Frequency (MHz) $P_{O} = -5dBm/tone$, 2MHz tone spacing



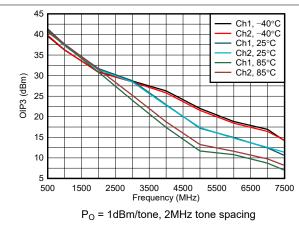
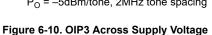
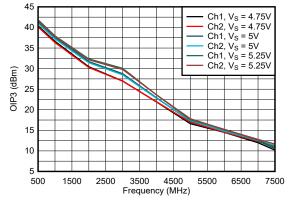


Figure 6-11. OIP3 Across Temperature





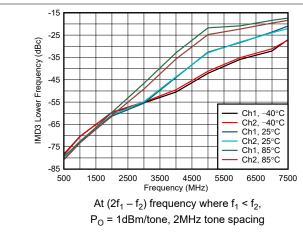
P_O = 1dBm/tone, 2MHz tone spacing

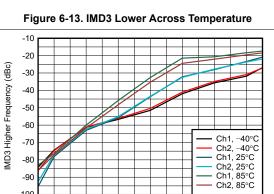
Figure 6-12. OIP3 Across Supply Voltage

7500



at T_A = 25°C, V_{S+} = 5V, V_{S-} = 0V, floating VOCM, PD, and MODE pins, V_{ICM} = mid-supply, D2D ac-coupled input/output configuration with $Z_S = 100\Omega$, $Z_L = 100\Omega$, external input resistor network (see Figure 8-3), inputs de-embedded up to R_{IN_SH} and outputs up to the device pins, ambient temperatures shown, and resistor network included as part of DUT characteristic plots (unless otherwise noted)





At $(2f_2 - f_1)$ frequency where $f_1 < f_2$, P_O = 1dBm/tone, 2MHz tone spacing

3500 4500 Frequency (MHz)

6500

Figure 6-15. IMD3 Higher Across Temperature

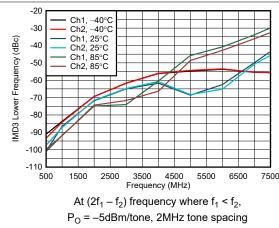
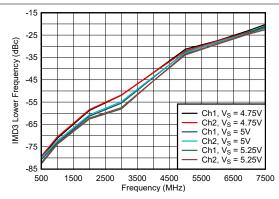
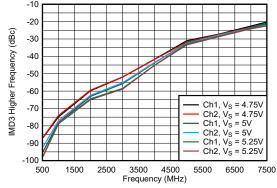


Figure 6-17. IMD3 Lower Across Temperature



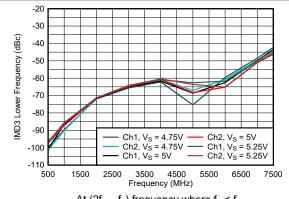
At $(2f_1 - f_2)$ frequency where $f_1 < f_2$, P_O = 1dBm/tone, 2MHz tone spacing

Figure 6-14. IMD3 Lower Across Supply Voltage



At $(2f_2 - f_1)$ frequency where $f_1 < f_2$, P_O = 1dBm/tone, 2MHz tone spacing

Figure 6-16. IMD3 Higher Across Supply Voltage

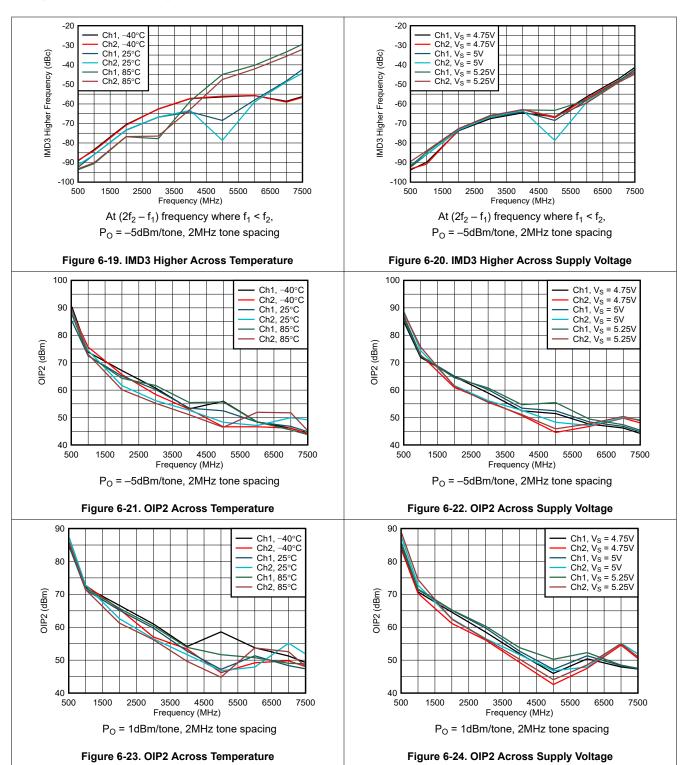


At $(2f_1 - f_2)$ frequency where $f_1 < f_2$, $P_O = -5 dBm/tone$, 2MHz tone spacing

Figure 6-18. IMD3 Lower Across Supply Voltage



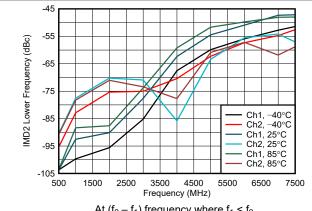
at T_A = 25°C, V_{S+} = 5V, V_{S-} = 0V, floating VOCM, PD, and MODE pins, V_{ICM} = mid-supply, D2D ac-coupled input/output configuration with Z_S = 100 Ω , Z_L = 100 Ω , external input resistor network (see Figure 8-3), inputs de-embedded up to R_{IN_SH} and outputs up to the device pins, ambient temperatures shown, and resistor network included as part of DUT characteristic plots (unless otherwise noted)





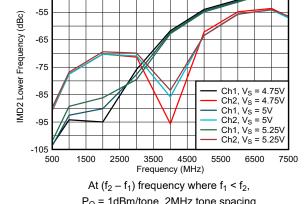
at T_A = 25°C, V_{S+} = 5V, V_{S-} = 0V, floating VOCM, PD, and MODE pins, V_{ICM} = mid-supply, D2D ac-coupled input/output configuration with $Z_S = 100\Omega$, $Z_L = 100\Omega$, external input resistor network (see Figure 8-3), inputs de-embedded up to R_{IN} SH and outputs up to the device pins, ambient temperatures shown, and resistor network included as part of DUT characteristic plots (unless otherwise noted)

-45



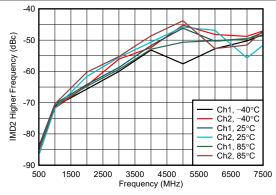
At $(f_2 - f_1)$ frequency where $f_1 < f_2$, P_O = 1dBm/tone, 2MHz tone spacing

Figure 6-25. IMD2 Lower Across Temperature



P_O = 1dBm/tone, 2MHz tone spacing

Figure 6-26. IMD2 Lower Across Supply Voltage



At $(f_1 + f_2)$ frequency where $f_1 < f_2$, P_O = 1dBm/tone, 2MHz tone spacing

-40 IMD2 Higher Frequency (dBc) -50 -60 Ch1, V_S = 4.75V Ch2, $V_S = 4.75V$ Ch1, $V_S = 5V$ Ch2, $V_S = 5V$ Ch1, Vs = 5.25\ Ch2, $V_S = 5.25V$ -90 1500 3500 500 4500 Frequency (MHz)

At $(f_1 + f_2)$ frequency where $f_1 < f_2$, P_O = 1dBm/tone, 2MHz tone spacing

Figure 6-27. IMD2 Higher Across Temperature

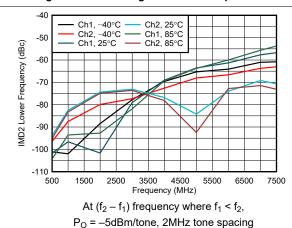
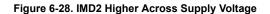
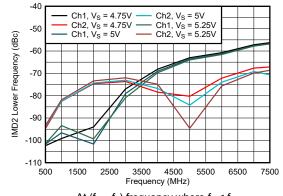


Figure 6-29. IMD2 Lower Across Temperature





At $(f_2 - f_1)$ frequency where $f_1 < f_2$, $P_O = -5$ dBm/tone, 2MHz tone spacing

Figure 6-30. IMD2 Lower Across Supply Voltage

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at T_A = 25°C, V_{S+} = 5V, V_{S-} = 0V, floating VOCM, PD, and MODE pins, V_{ICM} = mid-supply, D2D ac-coupled input/output configuration with Z_S = 100 Ω , Z_L = 100 Ω , external input resistor network (see Figure 8-3), inputs de-embedded up to R_{IN_SH} and outputs up to the device pins, ambient temperatures shown, and resistor network included as part of DUT characteristic plots (unless otherwise noted)

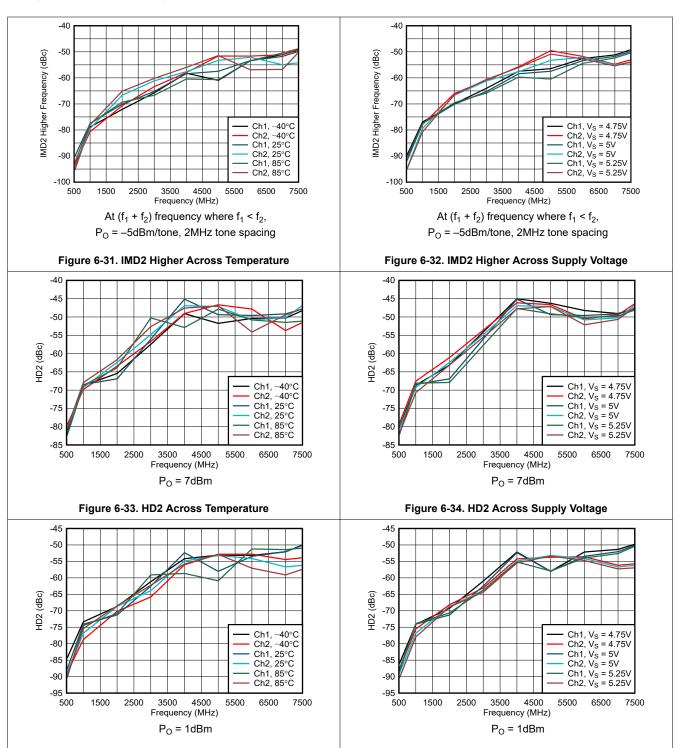
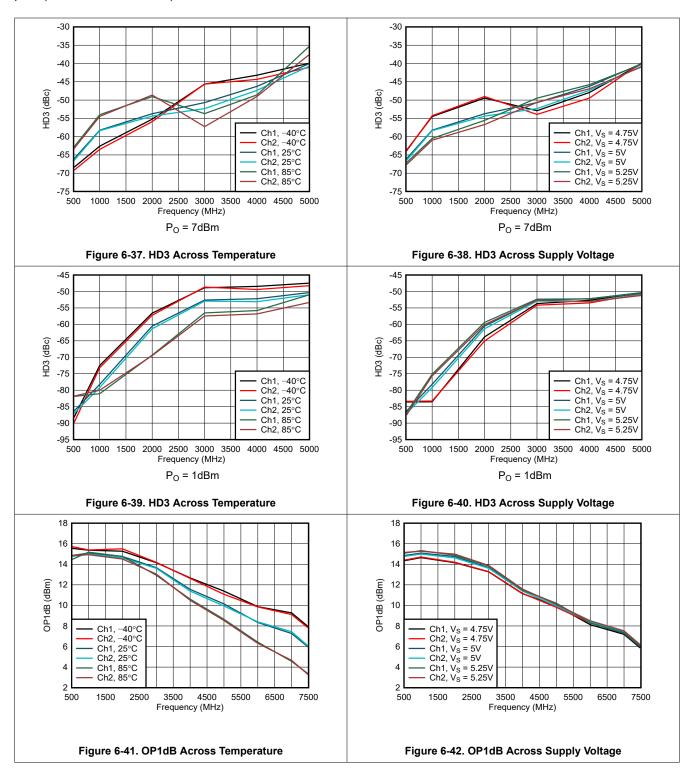


Figure 6-35. HD2 Across Temperature

Figure 6-36. HD2 Across Supply Voltage



at T_A = 25°C, V_{S+} = 5V, V_{S-} = 0V, floating VOCM, PD, and MODE pins, V_{ICM} = mid-supply, D2D ac-coupled input/output configuration with Z_S = 100 Ω , Z_L = 100 Ω , external input resistor network (see Figure 8-3), inputs de-embedded up to R_{IN_SH} and outputs up to the device pins, ambient temperatures shown, and resistor network included as part of DUT characteristic plots (unless otherwise noted)

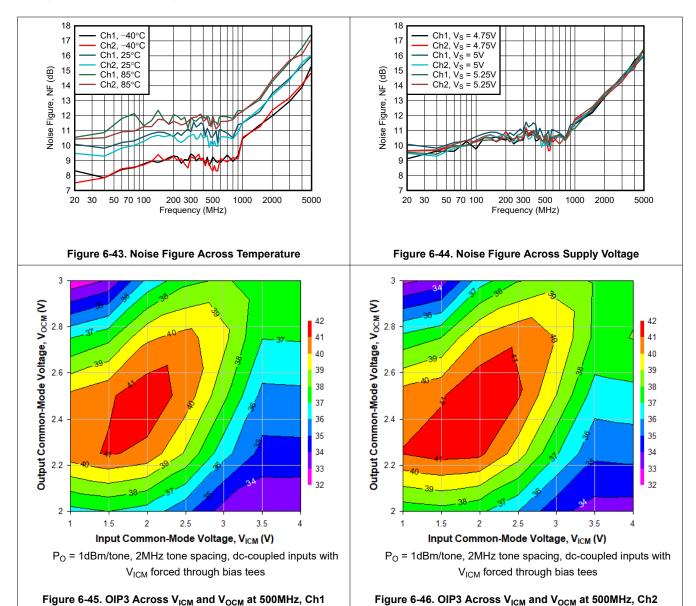


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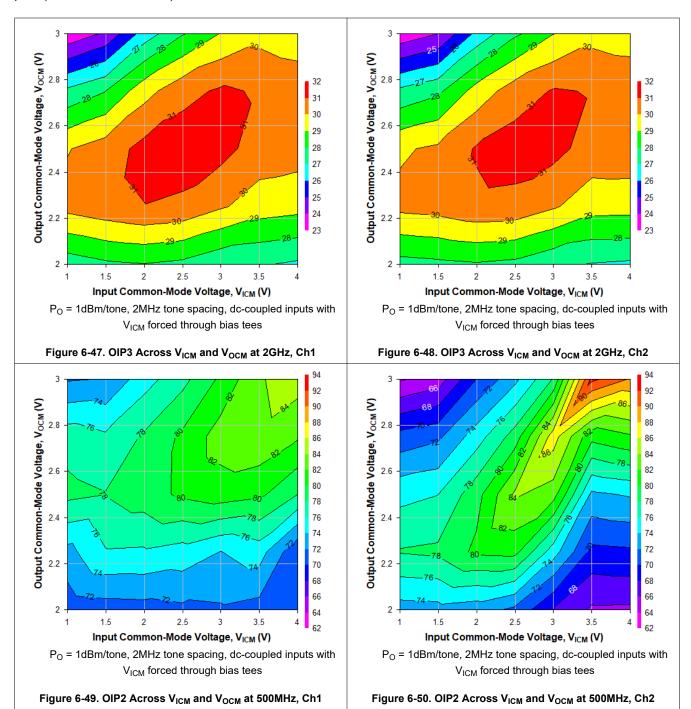


at $T_A = 25^{\circ}\text{C}$, $V_{S+} = 5\text{V}$, $V_{S-} = 0\text{V}$, floating VOCM, PD, and MODE pins, $V_{ICM} = \text{mid-supply}$, D2D ac-coupled input/output configuration with $Z_S = 100\Omega$, $Z_L = 100\Omega$, external input resistor network (see Figure 8-3), inputs de-embedded up to R_{IN_SH} and outputs up to the device pins, ambient temperatures shown, and resistor network included as part of DUT characteristic plots (unless otherwise noted)



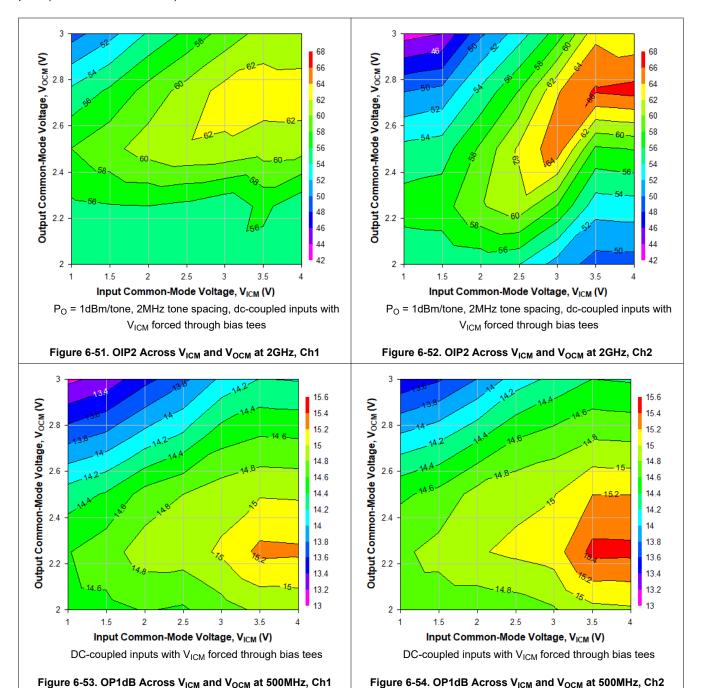


at T_A = 25°C, V_{S+} = 5V, V_{S-} = 0V, floating VOCM, PD, and MODE pins, V_{ICM} = mid-supply, D2D ac-coupled input/output configuration with Z_S = 100 Ω , Z_L = 100 Ω , external input resistor network (see Figure 8-3), inputs de-embedded up to R_{IN_SH} and outputs up to the device pins, ambient temperatures shown, and resistor network included as part of DUT characteristic plots (unless otherwise noted)



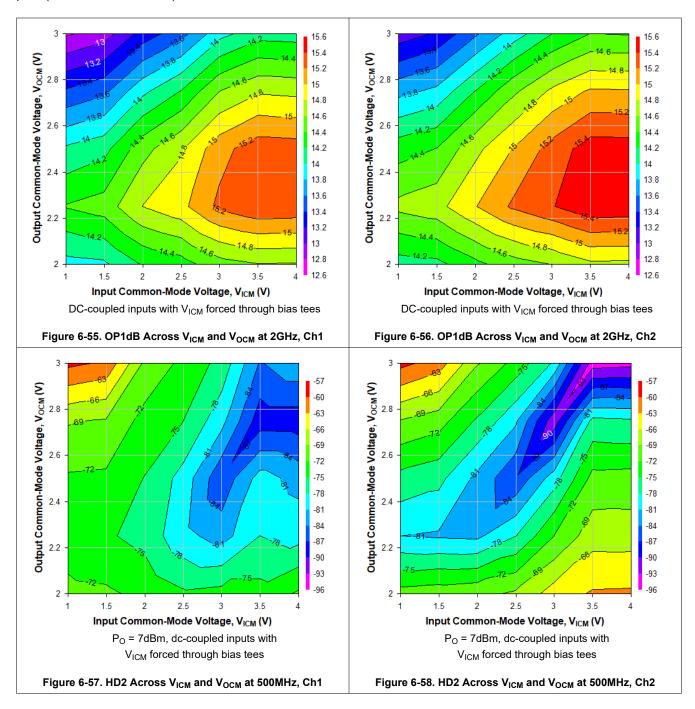


at T_A = 25°C, V_{S+} = 5V, V_{S-} = 0V, floating VOCM, PD, and MODE pins, V_{ICM} = mid-supply, D2D ac-coupled input/output configuration with $Z_S = 100\Omega$, $Z_L = 100\Omega$, external input resistor network (see Figure 8-3), inputs de-embedded up to R_{IN_SH} and outputs up to the device pins, ambient temperatures shown, and resistor network included as part of DUT characteristic plots (unless otherwise noted)



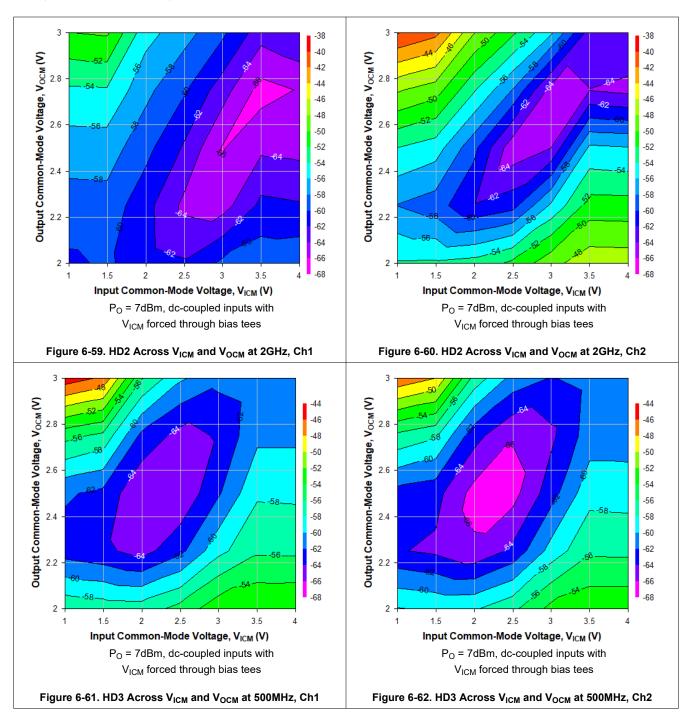


at T_A = 25°C, V_{S+} = 5V, V_{S-} = 0V, floating VOCM, PD, and MODE pins, V_{ICM} = mid-supply, D2D ac-coupled input/output configuration with Z_S = 100 Ω , Z_L = 100 Ω , external input resistor network (see Figure 8-3), inputs de-embedded up to R_{IN_SH} and outputs up to the device pins, ambient temperatures shown, and resistor network included as part of DUT characteristic plots (unless otherwise noted)



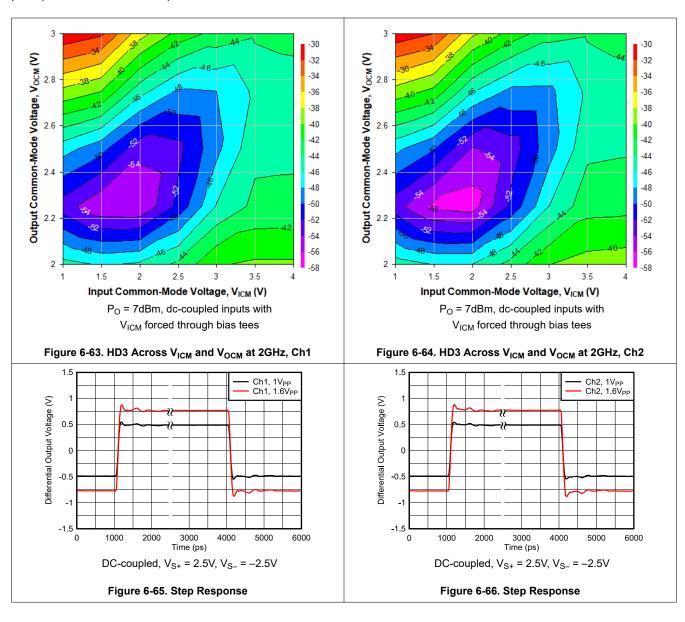


at T_A = 25°C, V_{S+} = 5V, V_{S-} = 0V, floating VOCM, PD, and MODE pins, V_{ICM} = mid-supply, D2D ac-coupled input/output configuration with $Z_S = 100\Omega$, $Z_L = 100\Omega$, external input resistor network (see Figure 8-3), inputs de-embedded up to R_{IN_SH} and outputs up to the device pins, ambient temperatures shown, and resistor network included as part of DUT characteristic plots (unless otherwise noted)



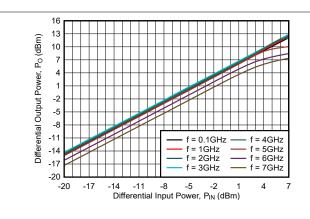


at T_A = 25°C, V_{S+} = 5V, V_{S-} = 0V, floating VOCM, PD, and MODE pins, V_{ICM} = mid-supply, D2D ac-coupled input/output configuration with Z_S = 100 Ω , Z_L = 100 Ω , external input resistor network (see Figure 8-3), inputs de-embedded up to R_{IN_SH} and outputs up to the device pins, ambient temperatures shown, and resistor network included as part of DUT characteristic plots (unless otherwise noted)





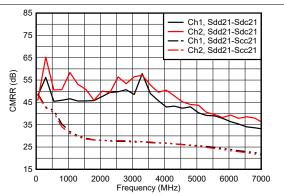
at T_A = 25°C, V_{S+} = 5V, V_{S-} = 0V, floating VOCM, PD, and MODE pins, V_{ICM} = mid-supply, D2D ac-coupled input/output configuration with Z_S = 100 Ω , Z_L = 100 Ω , external input resistor network (see Figure 8-3), inputs de-embedded up to R_{IN_SH} and outputs up to the device pins, ambient temperatures shown, and resistor network included as part of DUT characteristic plots (unless otherwise noted)

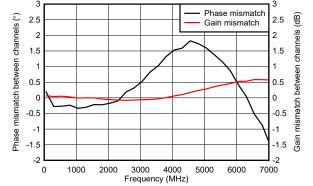


(dBm) 10 2 Differential Output Power, -5 -11 f = 4GHz = 0.1GHz f = 2GHzf = 6GHzf = 3GHz f = 7GHz -20 -20 -17 -11 -8 -5 Differential Input Power, P_{IN} (dBm)

Figure 6-67. Differential Output Power Across Differential Input Power, Ch1

Figure 6-68. Differential Output Power Across Differential Input Power, Ch2



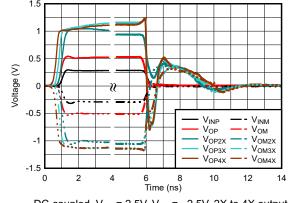


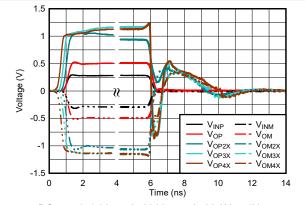
 P_{IN} = -20dBm at each driven input pin with 50 Ω source, c in Sdc21 and Scc21 is for common-mode

PIN = -20dBm at each driven input pin with 50Ω source



Figure 6-70. Gain and Phase Mismatch Between Channels





DC-coupled, V_{S+} = 2.5V, V_{S-} = -2.5V, 2X to 4X output voltages have input voltages 2 to 4 times V_{INP} and V_{INM}

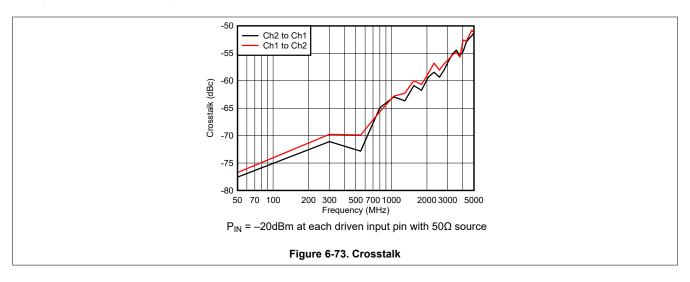
DC-coupled, V_{S+} = 2.5V, V_{S-} = -2.5V, 2X to 4X output voltages have input voltages 2 to 4 times V_{INP} and V_{INM}

Figure 6-71. Overdrive Recovery Response, Ch1

Figure 6-72. Overdrive Recovery Response, Ch2



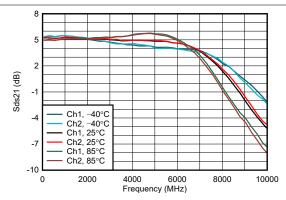
at T_A = 25°C, V_{S+} = 5V, V_{S-} = 0V, floating VOCM, PD, and MODE pins, V_{ICM} = mid-supply, D2D ac-coupled input/output configuration with Z_S = 100 Ω , Z_L = 100 Ω , external input resistor network (see Figure 8-3), inputs de-embedded up to R_{IN_SH} and outputs up to the device pins, ambient temperatures shown, and resistor network included as part of DUT characteristic plots (unless otherwise noted)



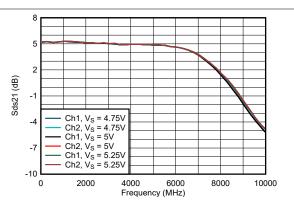


6.9 Typical Characteristics: S2D Configuration

at T_A = 25°C, V_{S+} = 5V, V_{S-} = 0V, floating VOCM, PD, and MODE pins, V_{ICM} = mid-supply, S2D ac-coupled input/output configuration with $R_{TERM} = 50\Omega$, $Z_S = 50\Omega$, $Z_L = 100\Omega$ (see Figure 8-1), input and outputs de-embedded up to the device pins, and ambient temperatures shown (unless otherwise noted)

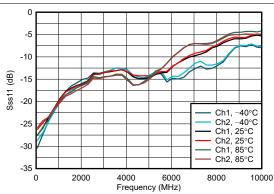


 $P_{IN} = -20 \text{dBm}$ with 50Ω source at all excited ports, nonexcited ports are terminated with 50Ω



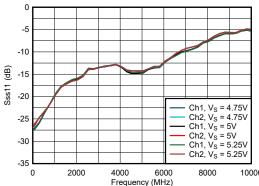
 $P_{IN} = -20$ dBm with 50Ω source at all excited ports, nonexcited ports are terminated with 50Ω





 $P_{IN} = -20$ dBm with 50Ω source at all excited ports, nonexcited ports are terminated with 50Ω

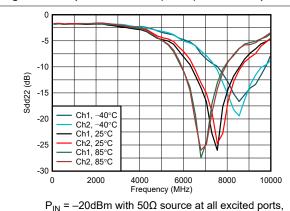
Figure 6-75. Power Gain (Sds21) Across Supply Voltage



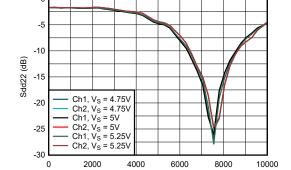
 P_{IN} = -20dBm with 50 Ω source at all excited ports, nonexcited ports are terminated with 50Ω

Figure 6-77. Input Return Loss (Sss11) Across Supply Voltage

Figure 6-76. Input Return Loss (Sss11) Across Temperature



nonexcited ports are terminated with 50Ω Figure 6-78. Output Return Loss (Sdd22) Across Temperature

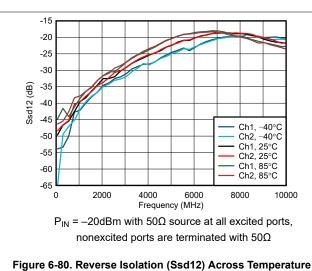


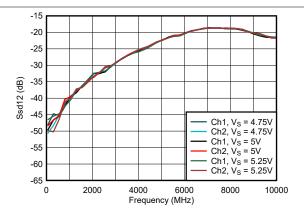
 P_{IN} = -20dBm with 50 Ω source at all excited ports, nonexcited ports are terminated with 50Ω

Figure 6-79. Output Return Loss (Sdd22) Across Supply Voltage

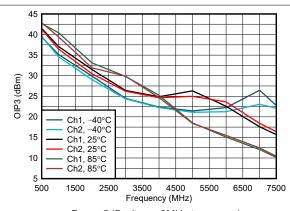


at T_A = 25°C, V_{S+} = 5V, V_{S-} = 0V, floating VOCM, PD, and MODE pins, V_{ICM} = mid-supply, S2D ac-coupled input/output configuration with $R_{TERM} = 50\Omega$, $Z_S = 50\Omega$, $Z_L = 100\Omega$ (see Figure 8-1), input and outputs de-embedded up to the device pins, and ambient temperatures shown (unless otherwise noted)



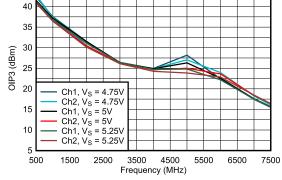


 $P_{IN} = -20$ dBm with 50Ω source at all excited ports, nonexcited ports are terminated with 50Ω



 $P_O = -5$ dBm/tone, 2MHz tone spacing

Figure 6-81. Reverse Isolation (Ssd12) Across Supply Voltage 40 35



 $P_O = -5dBm/tone$, 2MHz tone spacing

Figure 6-82. OIP3 Across Temperature

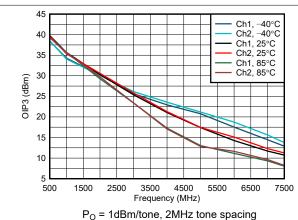
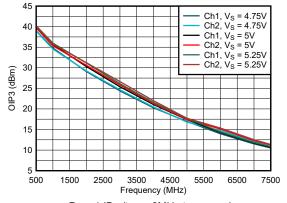


Figure 6-84. OIP3 Across Temperature

Figure 6-83. OIP3 Across Supply Voltage

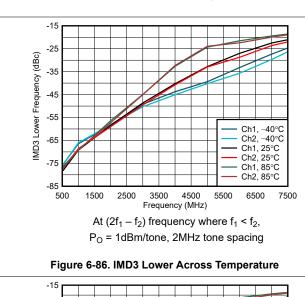


P_O = 1dBm/tone, 2MHz tone spacing

Figure 6-85. OIP3 Across Supply Voltage



at T_A = 25°C, V_{S+} = 5V, V_{S-} = 0V, floating VOCM, PD, and MODE pins, V_{ICM} = mid-supply, S2D ac-coupled input/output configuration with R_{TERM} = 50 Ω , Z_S = 50 Ω , Z_L = 100 Ω (see Figure 8-1), input and outputs de-embedded up to the device pins, and ambient temperatures shown (unless otherwise noted)



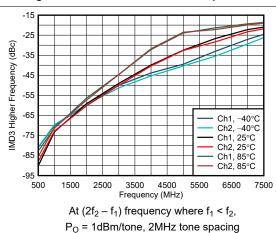


Figure 6-88. IMD3 Higher Across Temperature

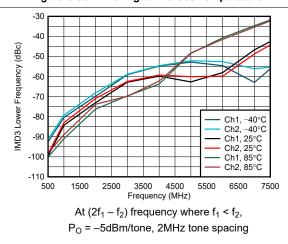
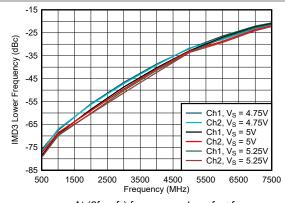
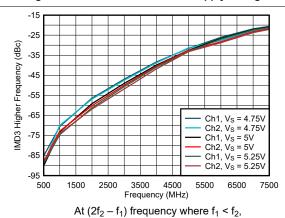


Figure 6-90. IMD3 Lower Across Temperature



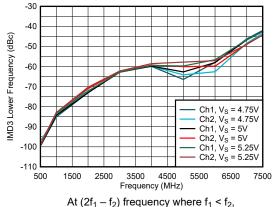
At $(2f_1 - f_2)$ frequency where $f_1 < f_2$, P_O = 1dBm/tone, 2MHz tone spacing

Figure 6-87. IMD3 Lower Across Supply Voltage



P_O = 1dBm/tone, 2MHz tone spacing

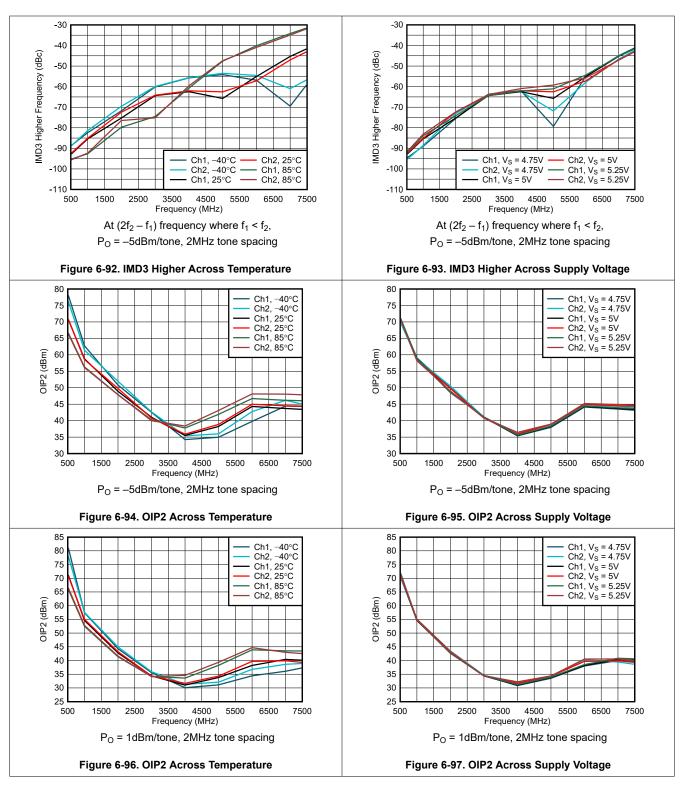
Figure 6-89. IMD3 Higher Across Supply Voltage



At $(2t_1 - t_2)$ frequency where $t_1 < t_2$, P_O = -5dBm/tone, 2MHz tone spacing

Figure 6-91. IMD3 Lower Across Supply Voltage







at T_A = 25°C, V_{S+} = 5V, V_{S-} = 0V, floating VOCM, PD, and MODE pins, V_{ICM} = mid-supply, S2D ac-coupled input/output configuration with R_{TERM} = 50 Ω , Z_S = 50 Ω , Z_L = 100 Ω (see Figure 8-1), input and outputs de-embedded up to the device pins, and ambient temperatures shown (unless otherwise noted)

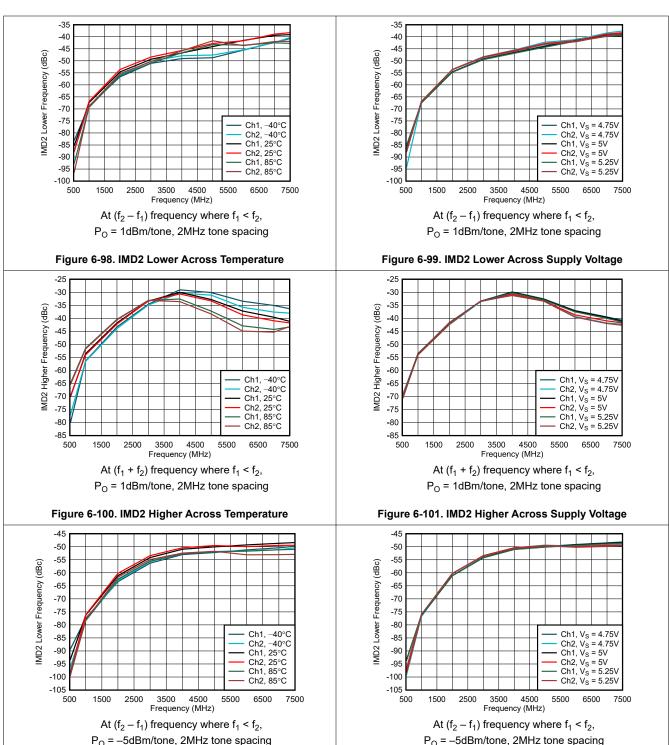
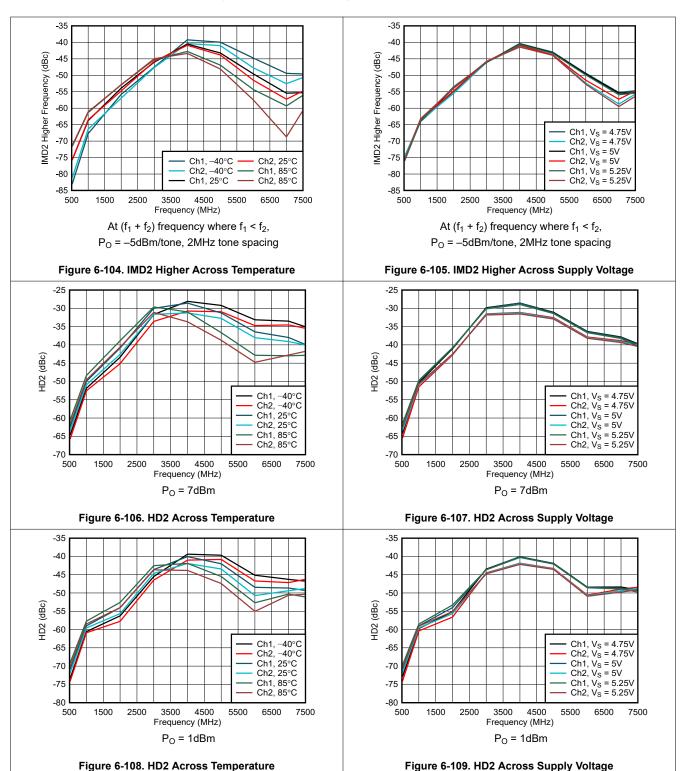


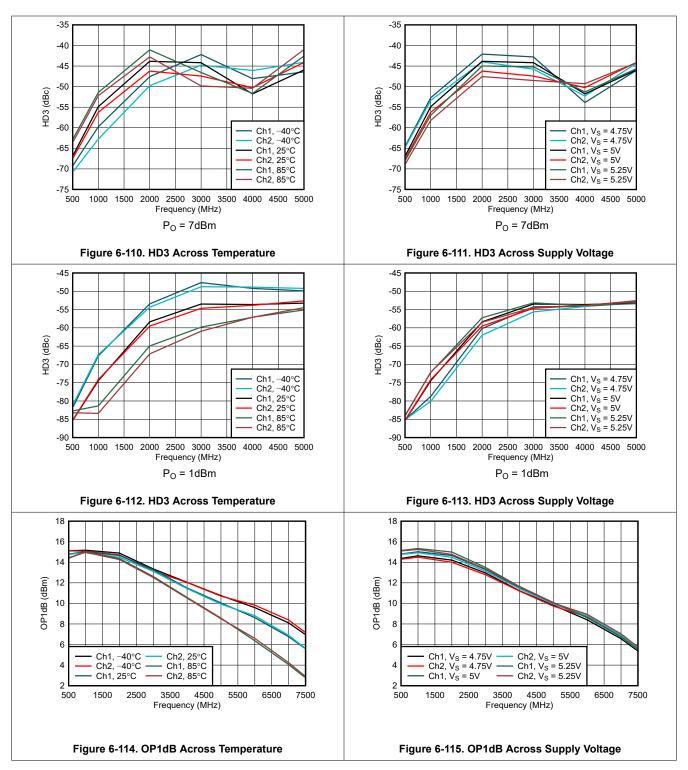
Figure 6-102. IMD2 Lower Across Temperature

Figure 6-103. IMD2 Lower Across Supply Voltage

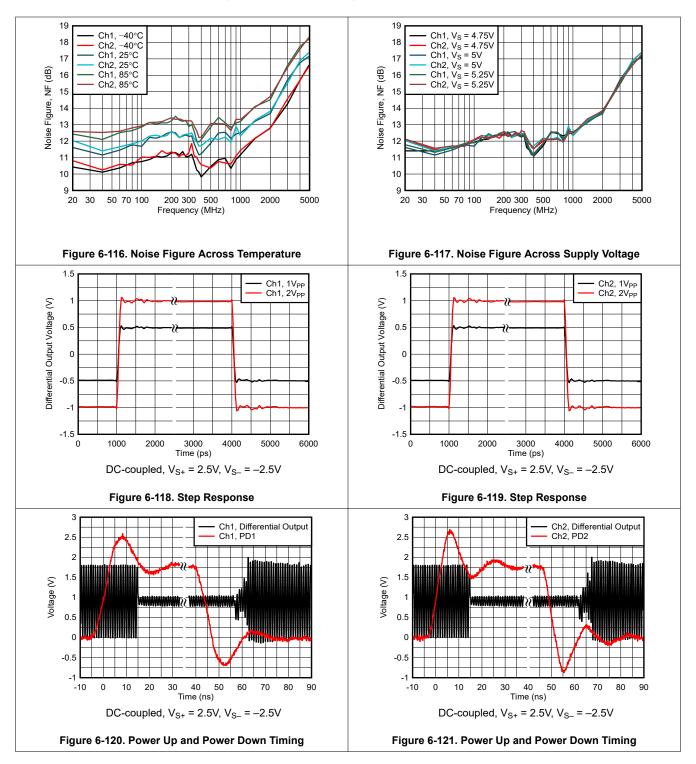














at T_A = 25°C, V_{S+} = 5V, V_{S-} = 0V, floating VOCM, PD, and MODE pins, V_{ICM} = mid-supply, S2D ac-coupled input/output configuration with R_{TERM} = 50 Ω , Z_S = 50 Ω , Z_L = 100 Ω (see Figure 8-1), input and outputs de-embedded up to the device pins, and ambient temperatures shown (unless otherwise noted)

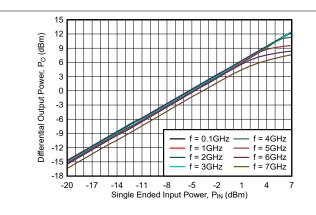
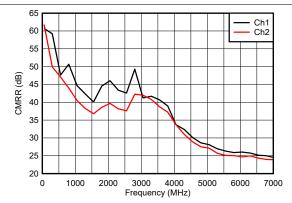
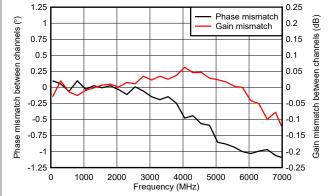


Figure 6-122. Differential Output Power Across Single-Ended Input Power, Ch1

Figure 6-123. Differential Output Power Across Single-Ended Input Power, Ch2



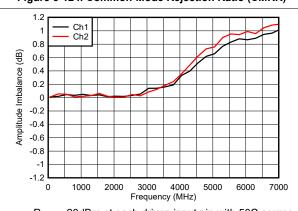


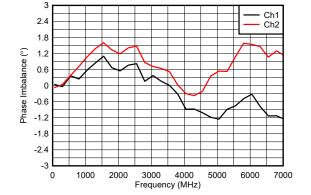
 P_{IN} = -20dBm at each driven input pin with 50 Ω source

 P_{IN} = -20dBm at each driven input pin with 50 Ω source









 P_{IN} = –20dBm at each driven input pin with 50Ω source

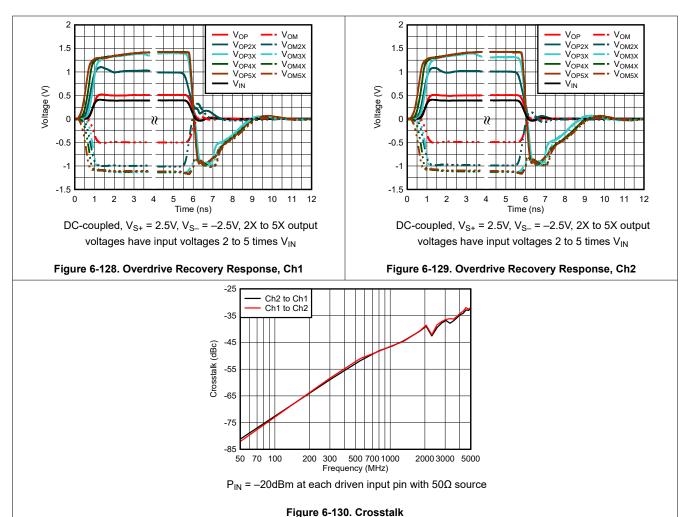
 P_{IN} = -20dBm at each driven input pin with 50 Ω source

Figure 6-126. Amplitude Imbalance

Figure 6-127. Phase Imbalance



at T_A = 25°C, V_{S+} = 5V, V_{S-} = 0V, floating VOCM, PD, and MODE pins, V_{ICM} = mid-supply, S2D ac-coupled input/output configuration with R_{TERM} = 50 Ω , Z_S = 50 Ω , Z_L = 100 Ω (see Figure 8-1), input and outputs de-embedded up to the device pins, and ambient temperatures shown (unless otherwise noted)



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7 Detailed Description

7.1 Overview

The TRF1305A2, TRF1305B2, and TRF1305C2 (TRF1305x2) devices are dual-channel, high-performance fully differential RF amplifiers optimized for very wideband signals. This device family is primarily designed to interface with high-speed and RF data converters that often require differential input (ADCs) and output (DACs) signaling. The TRF1305x2 can be dc or ac coupled, and configured as single-ended input and differential output (S2D) or differential input and differential output (D2D). The devices feature an output common-mode pin (VOCM) that allows the flexibility to set a desired common-mode output voltage. The VOCM pin sets the same output common-mode voltage for both shared channels. The amplifier allows the data converters to interface with a dc-coupled IQ demodulator or modulator if used in a direct conversion system. The TRF1305x2 family comes in three fixed power gain variants (15dB, 10dB, and 5dB), and has a closed-loop feedback-amplifier architecture.

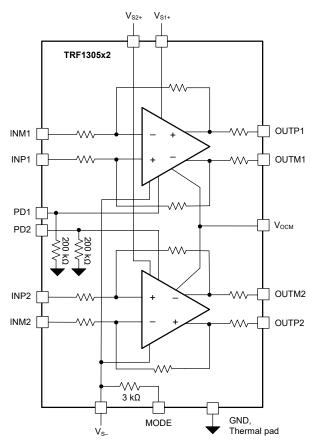
The devices are powered using two-rail supplies with a typical differential voltage of 5V between the positive and negative supplies, and usable in split- or single-supply configurations. A power-down feature is also available that allows each amplifier channel to be powered down individually.

The output of the amplifiers is low impedance. Use appropriate external series termination or resistive pad to match to an arbitrary impedance.

7.2 Functional Block Diagram

This section shows the functional block diagram of the dual-channel TRF1305x2. The output common-mode control pin is common for both channels.

There are certain common internal circuits that are powered by both VS1+ and VS2+. Therefore, short both VS1+ and VS2+ on the board and supply both with a voltage even if only one channel is used. The negative supply, V_{S-} , is shared by both the channels.



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7.3 Feature Description

The TRF1305x2 includes the following key features:

- Two-rail floating supply with supply-independent thermal pads
 - Connect the thermal pads to GND
 - RF signals and PDx pins referenced to GND
- Single-supply or split-supply operation
- Supports single-ended and differential input configurations
- Performance-optimized preset fixed-gain variants
- Output common-mode control
- MODE pin: V_{ICM} range extension closer to V_{S+} or V_{S-} modes
- · Digital-logic-controllable power-down option

7.3.1 Fully Differential RF Amplifier

The TRF1305x2 are voltage-feedback fully differential amplifiers (FDAs) with wide bandwidth. The amplifiers are designed for a differential power gain of 15dB, 10dB, or 5dB depending on the device variant. These amplifiers have excellent time-domain specifications with high slew rate, high input and output common-mode ranges, and fast transient settling time.

The output average voltage (common-mode) of the FDA device is controlled by a separate common-mode loop. The target output common-mode voltage is set by the VOCM input pin.

7.3.2 Output Common-Mode Control

Figure 7-1 shows a functional diagram of the output common-mode control. Internally, the VOCM pin potential is set by the LDO output voltage that is equal to V_{S-} + 2.5V connected through a 2.5kΩ resistor.

Floating the VOCM pin is allowed. The output common-mode voltage at the output pins, OUTPx and OUTMx, defaults to the LDO output voltage of V_{S-} + 2.5V when VOCM pin is floated. Floating the VOCM pin results in a V_{OCM} voltage equal to midsupply when V_S = 5V. If the VOCM pin is driven, then drive the pin from a low-impedance source. Limit the value of R_{OCM} to less than 25 Ω for accurate reflection of the forced V_{OCM} voltage at the device outputs.

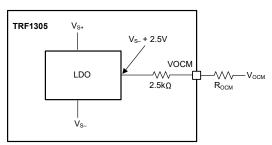


Figure 7-1. Output Common-Mode Control

7.3.3 Internal Resistor Configuration

Figure 7-2 shows the internal resistor configurations of TRF1305x2. Table 7-1 provides the values of these resistors for different gain variants.

Product Folder Links: TRF1305C2



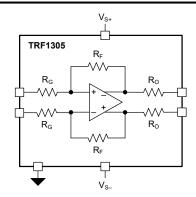


Figure 7-2. TRF1305x2 Internal Resistor Configuration

Table 7-1. Resistor Values

| DEVICE NAME | GAIN (dB) | R _G (Ω) | R _F (Ω) | R _O (Ω) |
|-------------|-----------|--------------------|--------------------|--------------------|
| TRF1305A2 | 15 | 6.25 | 258 | 4 |
| TRF1305B2 | 10 | 12.5 | 161 | 4 |
| TRF1305C2 | 5 | 17 | 97 | 4 |

7.4 Device Functional Modes

7.4.1 MODE Pin

The TRF1305x2 have additional useful features that are configurable using the MODE pin. To select the device mode, either connect a $\pm 2\%$ maximum tolerance pullup resistor between the MODE pin and VS2+, or force a voltage on the MODE pin. Internally, the MODE pin is referenced to V_{S-} through a $3k\Omega$ resistor (see Section 7.2). The selected mode applies to both channels.

Table 7-2 provides the value of the pullup resistor for each mode, the expected voltage (V_{MODE}) at the MODE pin when the pullup resistor is used, or the necessary V_{MODE} voltage to set the device mode and the mode configurations. The V_{MODE} voltage thresholds are approximately midway between the typical V_{MODE} voltage of the adjacent mode. If mode functionality is used, use a decoupling capacitor on the MODE pin.

Table 7-2. MODE Pin Configuration

| MODE NUMBER | PULLUP RESISTOR TO VS2+ (±2% MAXIMUM TOLERANCE) MODE PIN VOLTAGE V _{MODE} (V) | | V _{ICM} RANGE EXTENSION ⁽¹⁾ | | | | | |
|-------------|----------------------------------------------------------------------------------------------|-------------------------|---------------------------------------------------------------------|--|--|--|--|--|
| 0 | OPEN | V _{S-} | Default V _{ICM} range | | | | | |
| 1 | 25.6kΩ | V _{S-} + 0.52V | Low side, extends V_{ICM} range closer to $V_{\text{S-}}$ | | | | | |
| 2 | 12.8kΩ | V _{S-} + 0.94V | High side, extends V_{ICM} range closer to $V_{\text{S+}}$ | | | | | |
| N/A | Do not use pullup resistor < 10kΩ, do not set $V_{MODE} > V_{S-} + 1.15V$ | | | | | | | |

⁽¹⁾ Only available in D2D configuration.

To switch the mode without turning the supplies off, use a switch or MUX connected between the pullup resistor options and VS2+, or force a mode-appropriate V_{MODE} voltage. However, best practice is to power down the device using the power-down feature between mode changes; see also Section 7.4.2. The low-side V_{ICM} range extension mode sources current, and the high-side sinks current; see also the following section, *Input Common-Mode Extension*. Ensure that the external circuitry is ready to sink or source these currents before the device is put in the active mode from the powered-down state.

7.4.1.1 Input Common-Mode Extension

When configured in one of the V_{ICM} extension modes, the TRF1305C2 supports a V_{ICM} voltage closer to either V_{S+} or V_{S-} voltage instead of the default specified input common-mode range in the *Electrical Characteristics*. The V_{ICM} extension mode functions only in D2D configuration.



When configured in the low-side V_{ICM} extension mode, the TRF1305C2 supports a 500mV lower input common-mode voltage than the default option. For example, the lower limit of the V_{ICM} voltage range extends from a default value of V_{S-} + 1.5V to V_{S-} + 1V for the TRF1305C2 variant, and the higher limit also shifts lower from a default value of V_{S-} + 3.5V to V_{S-} + 3V. At the lowest V_{ICM} voltage, approximately 15mA current is sunk by the external circuitry connected to the INPx and INMx pins.

When configured in the high-side V_{ICM} extension mode, the TRF1305C2 supports a 500mV higher input common-mode voltage than the default option. For example, the higher limit of V_{ICM} voltage range extends from a default value of $V_{S-} + 3.5V$ to $V_{S-} + 4V$ for the TRF1305C2 variant, and the lower limit also shifts up from a default of $V_{S-} + 1.5V$ to $V_{S-} + 2V$. At the highest V_{ICM} voltage, approximately 15mA current is sourced by the external circuitry connected to the INPx and INMx pins.

Use resistors connected to supplies (or external current sources) to sink currents flowing out of the INPx and INMx pins during the low-side V_{ICM} extension mode, or to source currents flowing into the INPx and INMx pins during the high-side V_{ICM} extension mode.

7.4.2 Power-Down Mode

The TRF1305x2 have two bias modes, active and power-down, that are controlled by the voltage on the PD pin. The PD pin is referenced to GND through a $200k\Omega$ resistor; see also Section 7.2. If the $V_{S+} \ge 3.3V$ configuration is used, ensure that the PD voltage does not exceed the Absolute Maximum Ratings in case the high PD voltage is derived from V_{S+} .

With PD1 and PD2, control each channel independently, and individually power down each channel. Both 1.8V and 3.3V digital logic are supported for power-down control.

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8 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

8.1 Application Information

8.1.1 Input and Output Interface Considerations

8.1.1.1 Single-Ended Input

In the single-ended input configuration, one of the amplifier input pins is driven from a source while the other input is terminated with an external resistor. Figure 8-1 shows an ac-coupled, single-ended input configuration driven from and matched to a 50Ω source. Figure 8-1 shows how the non-driven INM pin is terminated with a 50Ω external resistor to match to a source with the same 50Ω impedance at the INP pin.

To configure the design in Figure 8-1 for single-ended, dc-coupled input, replace the ac-coupling capacitors with shorts, and externally bias both INP and INM pins to a voltage close to the mid-supply or within the common-mode limits of the amplifier.

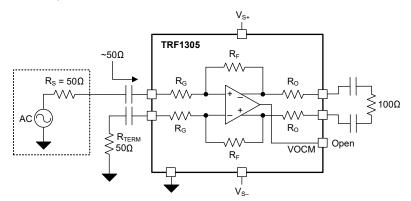


Figure 8-1. AC-Coupled, Single-Ended Input Matched to a 50Ω Source

8.1.1.2 Differential Input

Figure 8-2 shows how a simple network consisting of three resistors is used to match the differential input to a 100Ω differential source. Though the $1k\Omega$ shunt resistor, R_{IN} sh, does not have any impact at dc to low frequencies, the resistor is necessary to get the full wideband performance from TRF1305x2. Figure 8-3 shows the configuration for ac-coupled differential input designs. The resistors values shown in Figure 8-2 and Figure 8-3 work for all gain versions of the TRF1305x2 for an 100Ω input match to a 100Ω differential source.

Use high-frequency (RF) resistors (0201 preferred), for high-frequency (RF) matching.

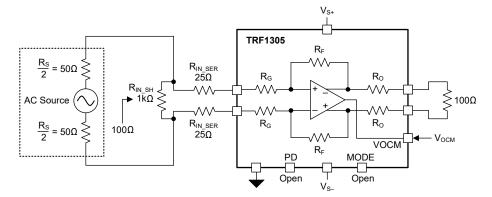


Figure 8-2. DC-Coupled Differential Input Matched to a 100Ω Differential Source

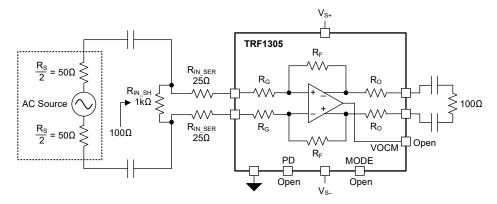


Figure 8-3. AC-Coupled Differential Input Matched to a 100Ω Differential Source

8.1.1.3 DC-Coupling Considerations

The TRF1305x2 accept a wide range of input dc common-mode (CM) voltages. Take into consideration the dc current loading of the source when the TRF1305x2 is dc coupled at the input. Figure 8-4 shows that when the input CM voltage, $V_{\rm ICM}$, is different than the output CM voltage, $V_{\rm OCM}$, a net dc current flow from or to the source occurs. Equation 1 shows the relationship that the source or sink current, $I_{\rm CM}$, has with the input and output CM voltages:

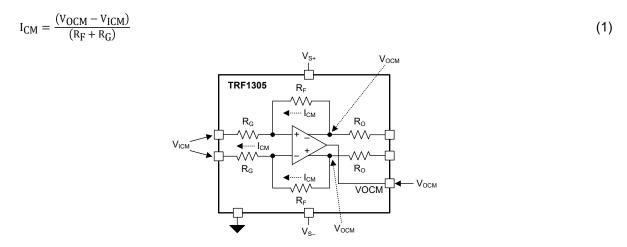


Figure 8-4. Net DC Current Flow When Input and Output Common-Mode Voltages are not Equal

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8.1.2 Gain Adjustment With External Resistors in a Differential Input Configuration

The TRF1305x2 allow minor gain adjustments by configuring the input external resistive network that is part of the differential input configuration. Figure 8-5 shows the external input network that comprises of a shunt resistor, R_{IN SH}, and two series input resistors, R_{IN SER}, connected to the input pins of the amplifier.

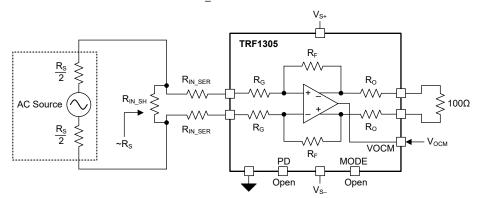


Figure 8-5. Gain Adjustment With External Resistor Network

Table 8-1 provides resistor configurations for a 100Ω differential source impedance.

| Table 8-1. Resistor Table for $R_S = 100\Omega$ | | | | | | | | |
|-------------------------------------------------|-------------------------|----|--|--|--|--|--|--|
| TRF1305C2 | | | | | | | | |
| POWER GAIN (dB) | R _{IN_SER} (Ω) | | | | | | | |
| 5 | 1000 | 25 | | | | | | |
| 4 | 434 | 30 | | | | | | |
| 3 | 288 | 36 | | | | | | |
| 2 | 222 | 42 | | | | | | |
| 1 | 184 | 49 | | | | | | |
| 0 | 160 | 57 | | | | | | |

Table 8-1 Resistor Table for R. = 1000

Use external resistive attenuation network only for small gain adjustments because there is a dB-to-dB noise figure degradation with the resistive attenuators. Use an amplifier version that requires minimal attenuation for achieving the overall gain.

8.2 Typical Application

8.2.1 TRF1305C2 as ADC Driver in a Zero-IF Receiver

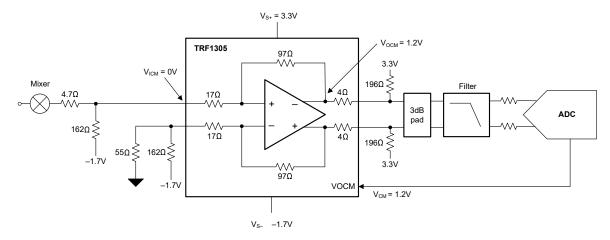


Figure 8-6. TRF1305C2 as ADC Driver in a Zero-IF Receiver

Consider a zero-IF (direct down conversion) application with an IQ demodulator interfaced to a pair of ADCs. In this case, the TRF1305C2 is used as an interface amplifier between the demodulator and the ADCs. The dc common-mode of the demodulator output and ADC input are different. The TRF1305C2 dc couples the demodulator to ADC without degrading the signal integrity of the signal chain.

8.2.1.1 Design Requirements

The primary design requirement for an IQ demodulator application is to interface a pair of passive mixers with an RF ADC. The mixers have a 0V common-mode voltage. The ADC requires an input common-mode voltage of 1.2V with full-scale swing of 1.35V_{PP}. Choose the power supplies, and design the input/output network for the TRF1305C2 as the ADC driver amplifier, to perform the dc level shifting and amplification function.

8.2.1.2 Detailed Design Procedure

The first step is to choose the TRF1305C2 supplies. Ensure that the midsupply voltage, $V_{\text{MIDSUPPLY}}$, is between the ADC common-mode (CM) voltage and the mixer CM voltage. V_{MIDSUPPLY} is typically positioned closer to the ADC CM because the output CM range of the amplifier is less than the input CM range. Ensure that the dc of the signal at the input and output of the amplifier are within the valid operating common-mode voltage range. Use the MODE pin for cases where an extended range of the input CM is required.

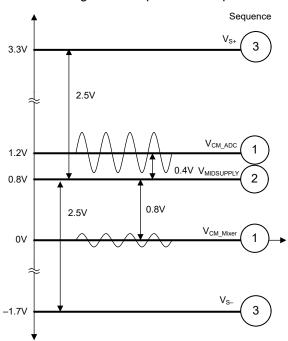


Figure 8-7. Choosing Supply Voltages With Given Common-Mode Voltages

Figure 8-7 shows how V_{MIDSUPPLY} is chosen to be 0.8V, so that the amplifier input has a CM offset from $V_{\text{MIDSUPPLY}}$ of 0.8V and output has a CM offset from $V_{\text{MIDSUPPLY}}$ of 0.4V (1.2V – 0.8V). The CM offsets are within the valid common-mode range of the amplifier, so the supplies of the TRF1305C2 are chosen to be V_{S+} = 3.3V (0.8V + 2.5V) and $V_{S-} = -1.7V$ (0.8V - 2.5V). Further optimization in the choice of supply is possible by selecting the input and output CM voltages for the best OIP3 performance. Section 8.2.1.3 has contour graphs that show OIP3 across input and output common-mode voltages.

The output CM is greater than the input CM; therefore, a net 10.5mA ((1.2V - 0V) / (97 Ω + 17 Ω)) dc current flows from the output to input through the internal feedback resistors. Depending on the choice of the passive mixer, this current can required to be sunk outside the mixer so that the bias conditions of the mixer are not disturbed. A 162Ω pulldown resistor connected to the INP pin to -1.7V supply is adequate. If the 10.5mA dc current is sourced entirely from the amplifier, then the output headroom can be affected. Therefore, source the current externally from the supply using a pair of pullup resistors connected to the amplifier outputs; 196Ω pullup resistors from OUTP and OUTM to 3.3V are adequate.

Product Folder Links: TRF1305C2



The I-channel mixer output has a 50 Ω port and is connected to the amplifier INP pin through a small (4.7 Ω) series resistor. The INM pin is terminated to ground through a 55Ω resistor and to -1.7V through a 162Ω resistor. This configuration allows the amplifier to have the same input impedance at each of the INP and INM input pins. The impedance of the mixer is close to 43Ω and provides better than a -20dB return loss (theoretically). Be aware that there is some drop in the gain due to these resistor networks. The values of the resistors chosen in Figure 8-6 are a good starting point; in practice, some adjustment is often needed to simultaneously meet the dc conditions and the RF performance.

At the amplifier output, a 3dB pad with a 100Ω differential impedance is used to match to the antialiasing filter with a 100Ω differential input impedance. The filter output is connected to ADC with appropriate matching. Figure 8-6 only shows the I-channel; the Q-channel has an identical configuration.

8.2.1.3 Application Curves

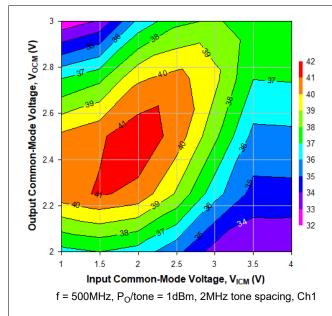


Figure 8-8. OIP3 Across Input and Output **Common-Mode Voltage**

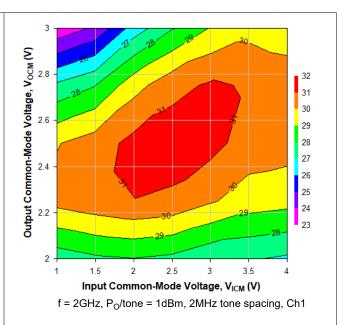


Figure 8-9. OIP3 Across Input and Output **Common-Mode Voltage**



8.3 Power Supply Recommendations

8.3.1 Supply Voltages

For the TRF1305x2, short both the VS1+ and VS2+ supply pins together to the same voltage for proper device operation. The typical differential supply between VS+ and VS- is 5V. The VS+ and VS- supply pins can be floated with respect to the thermal pad within the specified range listed in the *Absolute Maximum Ratings* and *Recommended Operating Conditions*.

8.3.2 Single-Supply Operation

The VS- pin is connected to ground in the single-supply configuration. Single-supply operation is most convenient in ac-coupled configurations because the dc common-mode voltages of the source at the inputs and the driven circuit at the outputs are inherently decoupled.

8.3.3 Split-Supply Operation

In split-supply configuration, choose the V_{S+} and V_{S-} voltages to be within the ranges specified in the *Absolute Maximum Ratings* and *Recommended Operating Conditions*. The TRF1305x2 allows choosing negative voltages for the V_{S-} supply, thereby allowing the flexibility to choose input and output common-mode voltages according to the input network and output network requirements.

8.3.4 Supply Decoupling

The VS+ and VS- supply pins are decoupled individually to ground using external capacitors. For the TRF1305x2, VS+ decoupling can be split between VS1+ to GND and VS2+ to GND separately for ease of board layout. Place the decoupling capacitors close to the device supply pins.

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Product Folder Links: TRF1305C2



8.4 Layout

8.4.1 Layout Guidelines

The TRF1305x2 devices are wideband closed-loop feedback amplifiers. When designing with wideband RF amplifiers that have high gain, take certain board layout precautions to maintain stability and optimized performance. Use a multilayer board to maintain signal integrity, power integrity, and thermal performance.

Route the RF input and output lines as grounded coplanar waveguide (GCPW) lines. Ground pins are the reference for the RF signals. Ensure that the second layer of the PCB has a continuous ground layer without any ground cutouts in the vicinity of the amplifier. To minimize phase imbalance, match the length of the output differential lines of both channels. Length matching the input traces is also important, especially if the input configuration is differential. Use small-footprint, passive components wherever possible.

For good heat dissipation, connect the device thermal pad to the board ground planes using thermal vias under the device. For improved heat dissipation, connect the device thermal pad to the top layer ground plane of the board.

8.4.1.1 Thermal Considerations

The TRF1305x2 are packaged in a WQFN-FCRLF package that has excellent thermal properties. Connect the thermal pads underneath the devices to the thermally dissipative ground plane on the board. For good thermal design, use thermal vias to connect the thermal pad plane on the top layer of the PCB to the ground planes in the inner layers.

8.4.2 Layout Example

Figure 8-10 shows an example layout for the TRF1305x2 with a differential input configuration. Key areas are highlighted in the figure.

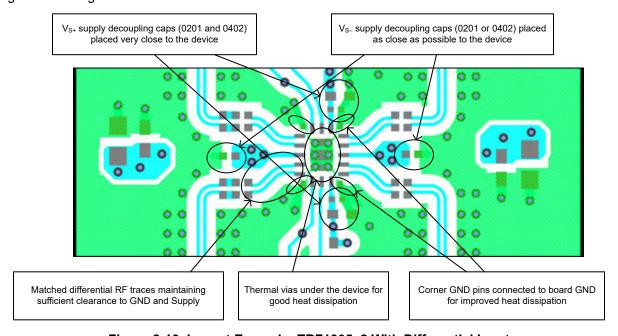


Figure 8-10. Layout Example: TRF1305x2 With Differential Input

The TRF1305C2 can be evaluated using EVM boards that can be ordered from the TRF1305C2 product folder. For more information about the evaluation board construction and test setup, see the *TRF1305x2 EVM User's Guide*.



9 Device and Documentation Support

9.1 Documentation Support

9.1.1 Related Documentation

For related documentation, see the following:

Texas Instruments, TRF1305x2-D2D EVM User's Guide

9.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

9.3 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

9.4 Trademarks

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9.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

9.6 Glossary

TI Glossary

46

This glossary lists and explains terms, acronyms, and definitions.

10 Revision History

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NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

| DATE | REVISION | NOTES | | | | |
|-------------|----------|-----------------|--|--|--|--|
| August 2025 | * | Initial Release | | | | |

11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

Product Folder Links: TRF1305C2

www.ti.com 6-Nov-2025

PACKAGING INFORMATION

| Orderable part number | Status | Material type | Package Pins | Package qty Carrier | RoHS (3) | Lead finish/ Ball material | MSL rating/ Peak reflow | Op temp (°C) | Part marking (6) |
|-----------------------|--------|---------------|--------------------------|-----------------------|-----------------|-------------------------------|----------------------------|--------------|------------------|
| | | | | | | (4) | (5) | | |
| TRF1305C2RYPR | Active | Production | VQFN-FCRLF (RYP) 16 | 2000 LARGE T&R | Yes | NIPDAU | Level-2-260C-1 YEAR | -40 to 105 | 1305C2 |

⁽¹⁾ Status: For more details on status, see our product life cycle.

- (3) RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.
- (4) Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.
- (5) MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.
- (6) Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





| A0 | Dimension designed to accommodate the component width |
|----|-----------------------------------------------------------|
| В0 | Dimension designed to accommodate the component length |
| K0 | Dimension designed to accommodate the component thickness |
| W | Overall width of the carrier tape |
| P1 | Pitch between successive cavity centers |

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

| Device | Package Type | Package Drawing | l . | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|---------------|-----------------|--------------------|-----|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| TRF1305C2RYPR | VQFN- FCRLF | RYP | 16 | 2000 | 330.0 | 12.4 | 2.8 | 3.3 | 1.2 | 4.0 | 12.0 | Q1 |

PACKAGE MATERIALS INFORMATION

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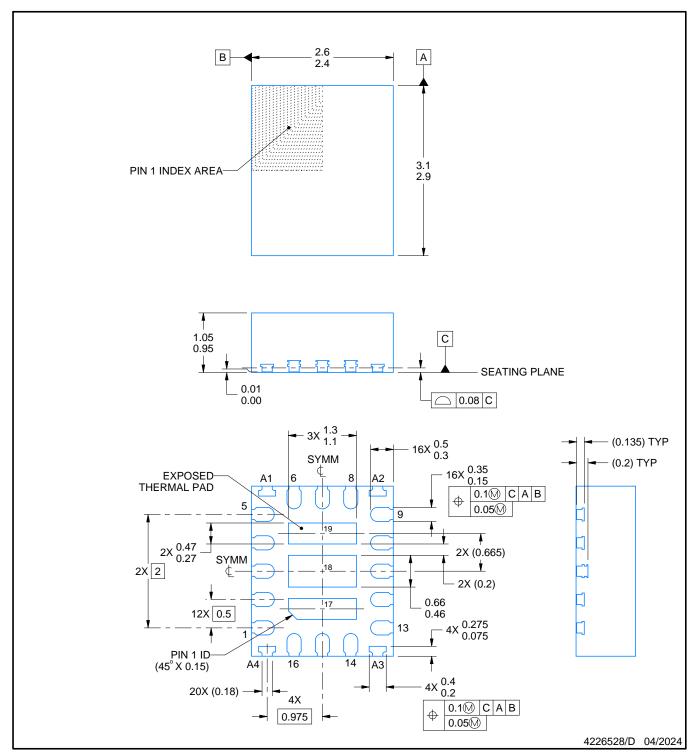


*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) | |
|---------------|--------------|-----------------|------|------|-------------|------------|-------------|--|
| TRF1305C2RYPR | VQFN-FCRLF | RYP | 16 | 2000 | 338.0 | 355.0 | 50.0 | |

VQFN-FCRLF - 1.05 mm max height

PLASTIC QUAD FLATPACK - NO LEAD

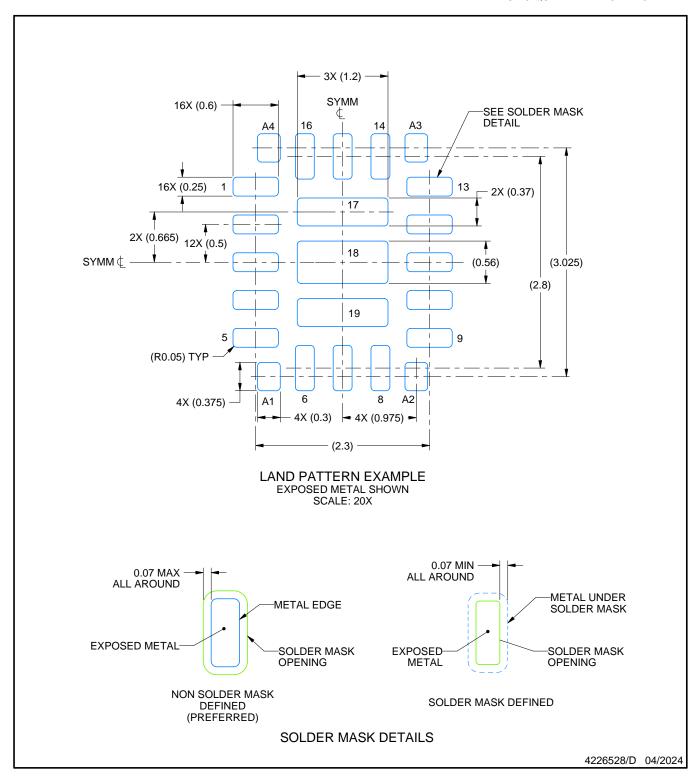


NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.



PLASTIC QUAD FLATPACK - NO LEAD

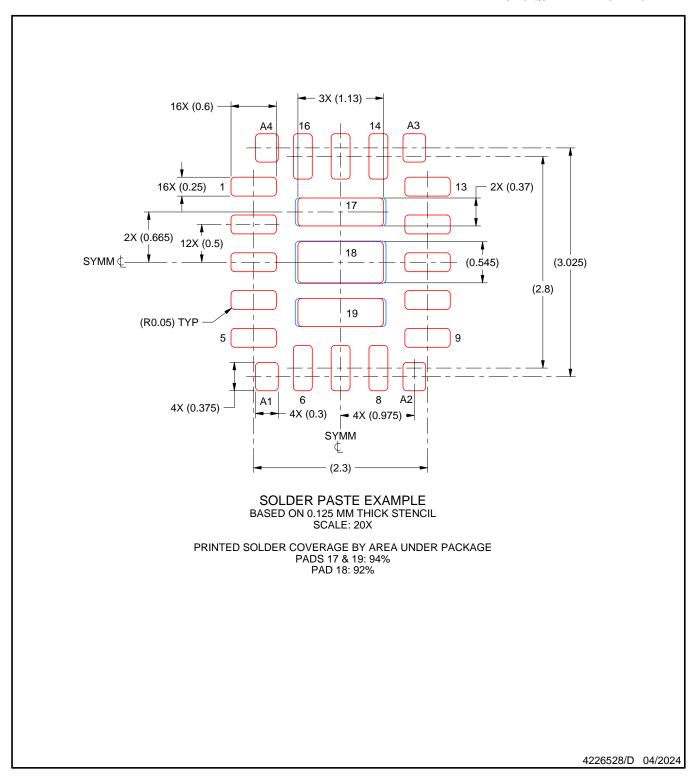


NOTES: (continued)

- 4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
- 5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



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